

具备 CAN FD（灵活数据速率）的 TCAN33x 3.3V CAN 收发器

1 特性

- 3.3V 单电源工作
- 数据速率高达 5Mbps (TCAN33xG 器件)
- 符合 ISO 11898-2 标准
- SOIC-8 和 SOT-23 封装选项
- 工作模式：
 - 正常模式 (所有器件)
 - 具有唤醒功能的低功耗待机模式 (TCAN334)
 - 静音模式 (TCAN330 , TCAN337)
 - 关断模式 (TCAN330 , TCAN334)
- $\pm 12\text{V}$ 的宽共模工作电压范围
- $\pm 14\text{V}$ 的总线引脚故障保护
- 总环路延迟 < 135ns
- 宽工作环境温度范围：-40°C 至 125°C
- 优化了未上电时的性能：
 - 总线和逻辑引脚为高阻抗 (运行总线或应用上无负载)
 - 上电/断电无干扰运行
- 出色的 EMC 性能
- 保护特性：
 - 总线终端的 ESD 保护
 - HBM ESD 保护超过 $\pm 25\text{kV}$
 - IEC61000-4-2 ESD 接触放电保护超过 $\pm 12\text{kV}$
 - 驱动器显性超时 (TXD DTO)
 - 接收器显性超时 (RXD DTO)
 - 故障输出引脚 (仅 TCAN337)
 - V_{CC} 欠压保护
 - 热关断保护
 - 总线引脚限流

2 应用

- 具有灵活数据速率网络的 CAN 中的 5Mbps 运行 (TCAN33xG 器件)
- 高负载 CAN 网络中的 1Mbps 运行
- 工业自动化、控制、传感器和驱动系统

- 楼宇、安全和温度控制自动化
- 电信基站状态和控制
- CANopen、DeviceNet、NMEA2000、ARINC825、ISO11783、CANaerospace 等 CAN 总线标准

3 说明

TCAN33x 器件系列与 ISO 11898 高速 CAN (控制器局域网) 物理层标准兼容。TCAN330、TCAN332、TCAN334 和 TCAN337 的数据传输速率均高达 1Mbps。TCAN330G、TCAN332G、TCAN334G 和 TCAN337G 器件的 ISO 11898-2 更新版本发布正在审理中 (包括 CAN FD 和定义环路延迟对称的附加时序参数)。这些器件具有许多保护特性，其中有一项驱动器和接收器显性超时 (DTO) 特性，可用以确保 CAN 网络的稳定性。该器件还集成了 12kV IEC-61000-4-2 ESD 接触放电保护，无需使用附加组件即可确保系统级的稳定性。

通过使用 3.3V 单电源，收发器可以直接连接 3.3V CAN 控制器/MCU。此外，这些器件完全兼容同一总线上的其他 5V CAN 收发器。

由于显性共模和隐性共模相匹配，这些器件具有出色的 EMC 性能。这些器件具有超低功耗的关断模式和待机模式，对电池供电型应用而言极具吸引力。

该系列器件提供便于插接的标准 8 引脚 SOIC 封装以及面向空间受限类应用的小型 SOT-23 封装。

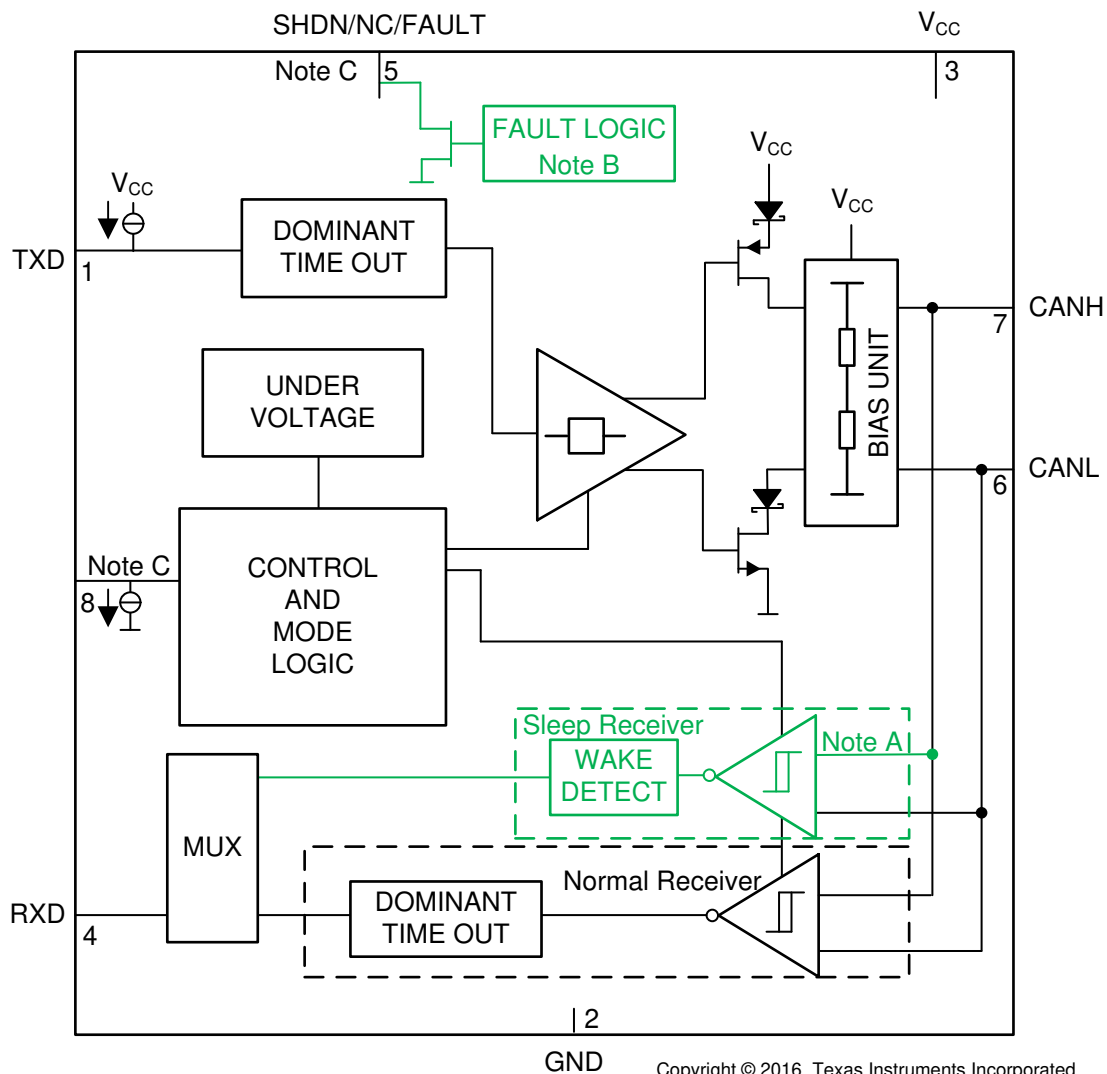
封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
TCAN330/G TCAN332/G TCAN334/G TCAN337/G	SOIC (8)	4.9mm × 6mm
	SOT-23 (8)	2.9mm × 1.6mm

(1) 有关所有可用封装，请参阅 节 9。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。





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A: Sleep Receiver and Wake Detect are device dependent options and are only available in TCAN334.

B: Fault Logic are only available in TCAN337.

C: Pin 5 and 8 functions are device dependent. Refer to Device Comparison Table.

方框图

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Device Options

DEVICE	PIN 5	PIN 8	DERATE	DESCRIPTION
TCAN330	SHDN	S	1 Mbps	Shutdown and silent modes
TCAN332	NC	NC	1 Mbps	Normal mode only
TCAN334	SHDN	STB	1 Mbps	Shutdown and standby with wake
TCAN337	FAULT	S	1 Mbps	Fault output and silent mode
TCAN330G	SHDN	S	5 Mbps	Shutdown and silent modes
TCAN332G	NC	NC	5 Mbps	Normal mode only
TCAN334G	SHDN	STB	5 Mbps	Shutdown and standby with wake
TCAN337G	FAULT	S	5 Mbps	Fault output and silent mode

4 Pin Configuration and Functions

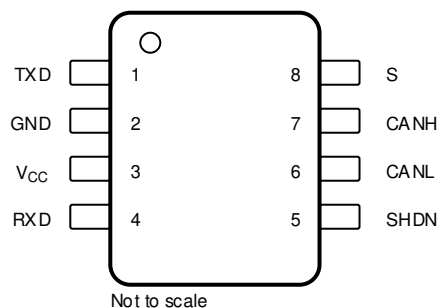


图 4-1. TCAN330 D, DCN Packages, 8-Pin SOIC, SOT-23, (Top View)

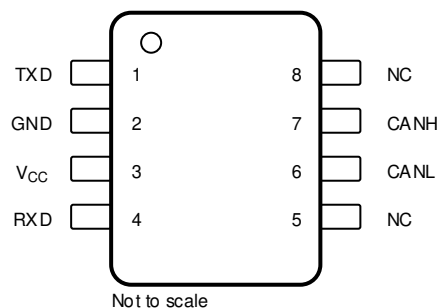


图 4-2. TCAN332 D, DCN Packages, 8-Pin SOIC, SOT-23, (Top View)

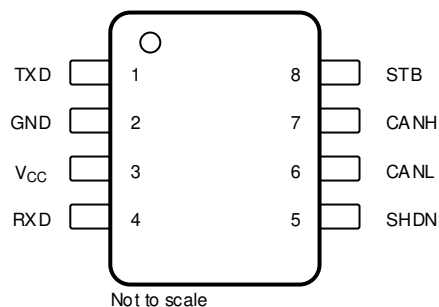


图 4-3. TCAN334 D, DCN Packages, 8-Pin SOIC, SOT-23, (Top View)

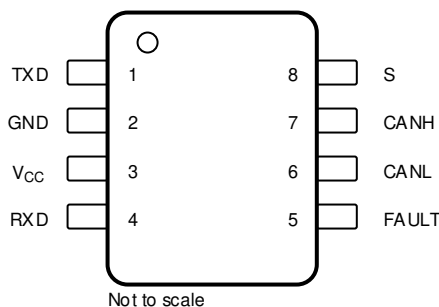


图 4-4. TCAN337 D, DCN Packages, 8-Pin SOIC, SOT-23, (Top View)

表 4-1. Pin Functions

NAME	PIN				I/O	DESCRIPTION
	TCAN330	TCAN332	TCAN334	TCAN337		
TXD	1	1	1	1	I	CAN transmit data input (LOW for dominant and HIGH for recessive bus states), integrated pull up
GND	2	2	2	2	GND	Ground connection
V _{CC}	3	3	3	3	Supply	3.3-V supply voltage
RXD	4	4	4	4	O	CAN receive data output (LOW for dominant and HIGH for recessive bus states), tri-state
SHDN	5	—	5	—	I	Drive high for shutdown mode. Internal pull-down.
NC	—	5	—	—	NC	No Connect - Not internally connected
FAULT	—	—	—	5	O	Open drain fault output pin.
CANL	6	6	6	6	I/O	Low level CAN bus line
CANH	7	7	7	7	I/O	High level CAN bus line
S	8	—	—	8	I	Drive high for silent mode, integrated pull down
NC	—	8	—	—	NC	No Connect - Not internally connected
STB	—	—	8	—	I	Drive high for low power standby mode, integrated pull down

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

	MIN	MAX	UNIT
Supply Voltage range, V_{CC}	- 0.3	5	V
Voltage at any bus terminal (CANH or CANL), $V_{(BUS)}$	- 14	14	V
Logic input terminal voltage range $V_{(Logic_Input)}$	- 0.3	5	V
Logic output terminal voltage range, $V_{(Logic_Output)}$	- 0.3	5	V
Logic output current, $I_{O(Logic)}$		8	mA
Operating junction temperature range, T_J	- 40	150	°C
Storage temperature, T_{stg}		150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to ground terminal.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	All pins except CANH and CANL	±4000	V
		Pins CANH and CANL	±25000	
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	All pins	±1500	
	IEC 61400-4-2 Contact Discharge	CANH and CANL terminals to GND	±12000	

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	3		3.6	V
$I_{OH(Logic)}$	Logic terminal HIGH level output current	- 2			mA
$I_{OL(Logic)}$	Logic terminal LOW level output current			2	
T_A	Operational free-air temperature	- 40		125	°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾			TCAN33x	TCAN33x	UNIT
			D (SOIC)	DCN (SOT-23)	
			8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance		114.4	154.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance		58.7	76.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance		55.2	49.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter		11.7	11.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter		54.6	49.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance		N/A	N/A	°C/W
P_D	Average power dissipation	$V_{CC} = 3.3\text{ V}$, $T_J = 27^\circ\text{C}$, $R_L = 60\ \Omega$, SHDN, S and STB at 0 V, Input to TXD at 500 kHz, 50% duty cycle square wave, $C_{L(RXD)} = 15\text{ pF}$	65	65	mW
T_{SD}	Thermal shutdown temperature		175	175	°C
T_{HYS}	Thermal shutdown hysteresis		5	5	°C

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

5.5 Electrical Characteristics

over operating free-air temperature range, $T_J = -40^\circ\text{C}$ to 150°C . All typical values are at 25°C and supply voltages of $V_{CC} = 3.3\text{ V}$, $R_L = 60\ \Omega$, (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
Supply								
I _{CC}	Supply current Normal Mode	Dominant	See 图 6-1. TXD = 0V, R _L = 60Ω, C _L = open, S, STB and SHDN = 0V. Typical Bus Load.				55	mA
			See 图 6-1. TXD = 0V, R _L = 50Ω, C _L = open, S, STB and SHDN = 0V. High Bus Load.				60	
		Dominant with bus fault	See 图 6-1. TXD = 0V, S, STB and SHDN = 0V, CANH = -12V, R _L = open, C _L = open				180	
		Recessive	See 图 6-1. TXD = V _{CC} , R _L = 50Ω, C _L = open, S, STB and SHDN = 0V				3.5	
	Supply Current: Silent Mode		See 图 6-1. TXD = V _{CC} , R _L = 50Ω, C _L = open, S = V _{CC}				2.5	μA
	Supply Current: Standby Mode		T _A < 85°C, STB at V _{CC} , RXD floating, TXD at V _{CC}				15	
			STB at V _{CC} , RXD floating, TXD at V _{CC}				20	
	Supply Current: Shutdown Mode		T _A < 85°C, SHDN at V _{CC} , RXD floating, TXD at V _{CC}				1	
			SHDN = V _{CC} , RXD floating, TXD at V _{CC}				2.5	
UV(V _{CC})	Rising under voltage detection on V _{CC} for protected mode					2.2	2.6	V
	Falling under voltage detection on V _{CC} for protected mode					1.65	2	
V _{HYS(UV_{VCC})}	Hysteresis voltage on UV(V _{CC})					200		mV
Driver								
V _{O(D)}	Bus output voltage (dominant)	CANH	See 图 6-3 and 图 6-2, TXD = 0V, S, STB and SHDN = 0V, R _L = 60Ω, C _L = open			2.45	V _{CC}	V
		CANL				0.5	1.25	
V _{O(R)}	Bus output voltage (recessive)		See 图 6-3 and 图 6-2, TXD = V _{CC} , STB, SHDN = 0V, S = 0V or V _{CC} ⁽¹⁾ , R _L = open (no load)			1.85		V

5.5 Electrical Characteristics (续)

over operating free-air temperature range, $T_J = -40^{\circ}\text{C}$ to 150°C . All typical values are at 25°C and supply voltages of $V_{CC} = 3.3\text{ V}$, $R_L = 60\ \Omega$, (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{OD(D)}$	Differential output voltage (dominant)	See 图 6-3 and 图 6-2, $\text{TXD} = 0\text{V}$, S, STB and SHDN = 0V , $50\ \Omega \leq R_L \leq 65\ \Omega$, $C_L = \text{open}$	1.6		3	V
		See 图 6-3 and 图 6-2, $\text{TXD} = 0\text{V}$, S, STB and SHDN = 0V , $45\ \Omega \leq R_L < 50\ \Omega$, $C_L = \text{open}$	1.5		3	
$V_{OD(R)}$	Differential output voltage (recessive)	See 图 6-3 and 图 6-2, $\text{TXD} = V_{CC}$, S, STB and SHDN = 0V , $R_L = 60\ \Omega$, $C_L = \text{open}$	- 120		12	mV
		$T_A < 85^{\circ}\text{C}$, See 图 6-3 and 图 6-2, $\text{TXD} = V_{CC}$, S, STB and SHDN = 0V , $R_L = \text{open}$ (no load), $C_L = \text{open}$	- 50		50	
		See 图 6-3 and 图 6-2, $\text{TXD} = V_{CC}$, S, STB and SHDN = 0V , $R_L = \text{open}$ (no load), $C_L = \text{open}$	- 50		100	
$V_{(\text{SYM})}$	Output symmetry (dominant and recessive) ($\text{CANH}_{\text{REC}} + \text{CANL}_{\text{REC}} - \text{CANH}_{\text{DOM}} - \text{CANL}_{\text{DOM}}$)	See 图 6-3 and 图 6-2, S, STB and SHDN = 0V , $R_L = 60\ \Omega$, $C_L = \text{open}$	- 400		400	mV
$I_{\text{OS(DOM)}}$	Short-circuit steady-state output current, Dominant	See 图 6-9, $V_{(\text{CANH})} = -12\text{V}$, CANL = open, $\text{TXD} = 0\text{V}$	- 200			mA
		See 图 6-9, $V_{(\text{CANL})} = 12\text{V}$, CANH = open, $\text{TXD} = 0\text{V}$			200	
$I_{\text{OS(REC)}}$	Short-circuit steady-state output current, Recessive	See 图 6-9, $-12\text{V} \leq V_{\text{BUS}} \leq 12\text{V}$, $V_{\text{BUS}} = \text{CANH} = \text{CANL}$, $\text{TXD} = V_{CC}$	- 5		5	mA

5.5 Electrical Characteristics (续)

over operating free-air temperature range, $T_J = -40^{\circ}\text{C}$ to 150°C . All typical values are at 25°C and supply voltages of $V_{CC} = 3.3\text{ V}$, $R_L = 60\ \Omega$, (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Receiver						
V_{IT}	Input threshold voltage, normal modes and selective wake modes	See 图 6-3 and 表 6-7	500		900	mV
V_{HYS}	Hysteresis voltage for input threshold, normal modes and selective wake modes			120		
V_{CM}	Common Mode Range: normal and silent modes		- 12		12	V
$V_{IT(STB)}$	Input Threshold, standby mode	- $2\text{V} < V_{CM} < 7\text{V}$ See 图 6-3 and 表 6-7	400		1150	mV
		- $12\text{V} < V_{CM} < 12\text{V}$ See 图 6-3 and 表 6-7	400		1350	mV
$I_{OFF(LKG)}$	Power-off (unpowered) bus input leakage current	$T_A < 85^{\circ}\text{C}$, CANH = CANL = 3.3V , V_{CC} to GND via $0\ \Omega$ and $47\text{k}\ \Omega$ resistor			6	μA
		CANH = CANL = 3.3V , V_{CC} to GND via $0\ \Omega$ and $47\text{k}\ \Omega$ resistor			12	
C_I	Input capacitance to ground (CANH or CANL)				20	pF
C_{ID}	Differential input capacitance				10	
R_{ID}	Differential input resistance	TXD = V_{CC} , Normal Mode	30		80	$\text{k}\ \Omega$
R_{IN}	Input resistance (CANH or CANL)	TXD = V_{CC} , Normal mode	15		40	
$R_{IN(M)}$	Input resistance matching: $[1 - (R_{IN(CANH)} / R_{IN(CANL)})] \times 100\ \%$	$V_{(CANH)} = V_{(CANL)}$	- 3%		3%	
TXD Terminal (CAN Transmit Data Input)						
V_{IH}	HIGH level input voltage		2			V
V_{IL}	LOW level input voltage				0.8	V
I_{IH}	HIGH level input leakage current	TXD = $V_{CC} = 3.6\text{V}$	- 2.5	0	3	μA
I_{IL}	LOW level input leakage current	TXD = 0V , $V_{CC} = 3.6\text{V}$	- 4	0	0	μA
$I_{LKG(OFF)}$	Unpowered leakage current	TXD = 3.6V , $V_{CC} = 0\text{V}$	- 2	0	2.5	μA
$I_{(CAP)}$	Input Capacitance			2.5		pF
RXD Terminal (CAN Receive Data Output)						
V_{OH}	HIGH level output voltage	See 图 6-3, $I_O = -2\text{mA}$	$0.8 \times V_{CC}$			V
V_{OL}	LOW level output voltage	See 图 6-3, $I_O = 2\text{mA}$		0.2	0.4	V
$I_{LKG(OFF)}$	Unpowered leakage current	RXD = 3.6V , $V_{CC} = 0\text{V}$	- 1	0	1	μA
STB/S/SHDN Terminals						
V_{IH}	HIGH level input voltage		2			V
V_{IL}	LOW level input voltage				0.8	V
I_{IH}	HIGH level input leakage current	STB, S, SHDN = $V_{CC} = 3.6\text{V}$	- 3	0	10	μA
I_{IL}	LOW level input leakage current	STB, S, SHDN = 0V , $V_{CC} = 3.6\text{V}$	- 4	0	1	μA
$I_{LKG(OFF)}$	Unpowered leakage current	STB, S, SHDN = 3.6V , $V_{CC} = 0\text{V}$	- 3	0	5	μA
FAULT Pin (Fault Output), TCAN337 only						
I_{CH}	Output current high level	FAULT = V_{CC} , See 图 6-11	- 10			μA
I_{CL}	Output current low level	FAULT = 0.4V , See 图 6-11	4	12		mA

- (1) The bus output voltage (recessive) is the same if the device is in normal mode with S terminal LOW, or if the device is in silent mode with the S terminal is HIGH.

5.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Device Switching Characteristics							
t _{PROP(LOOP)}	Total loop delay, driver input (TXD) to receiver output (RXD), recessive to dominant and dominant to recessive	See 图 6-6, S, STB and SHDN = 0V, R _L = 60Ω, C _L = 100pF, C _{L(RXD)} = 15pF		100	135	ns	
t _{PROP(LOOP)}	Total Loop delay in highly loaded network	See 图 6-6, S, STB and SHDN = 0V, R _L = 120Ω, C _L = 200pF, C _{L(RXD)} = 15pF		120	180	ns	
t _{BUS_SYM_2}	2 Mbps transmitted recessive bit width	See 图 6-7, S or STB = 0V, R _L = 60Ω, C _L = 100pF, C _{L(RXD)} = 15 pF, t _{BIT} = 500ns TCAN330G, TCAN332G, TCAN334G and TCAN337G only		435	530	ns	
t _{REC_SYM_2}	2 Mbps received recessive bit width			400	550	ns	
Δ t _{SYM_2}	2 Mbps receiver timing symmetry (t _{REC_SYM_2} - t _{BUS_SYM_2})			- 65	40	ns	
t _{BUS_SYM_5}	5 Mbps transmitted recessive bit width	See 图 6-7, S or STB = 0V, R _L = 60Ω, C _L = 100pF, C _{L(RXD)} = 15pF, t _{BIT} = 200ns TCAN330G, TCAN332G, TCAN334G and TCAN337G only		155	210	ns	
t _{REC_SYM_5}	5 Mbps received recessive bit width			120	220	ns	
Δ t _{SYM_5}	5 Mbps receiver timing symmetry (t _{REC_SYM_5} - t _{BUS_SYM_5})			- 45	15	ns	
t _{MODE}	Mode change time	See 图 6-4 and 图 6-5. R _L = 60 Ω , C _L = 100pF, C _{L(RXD)} = 15pF		5	10	μs	
t _{UV_RE-ENABLE}	Re-enable time after UV event	Time for device to return to normal operation from UV _(VCC) under voltage event			1000	μs	
t _{WK_FILTER}	Bus time to meet Filtered Bus Requirements for Wake Up Request	See 图 6-5, Standby mode. - 12V < V _{CM} < 12V		0.5	4	μs	
Driver Switching Characteristics							
t _{pHR}	Propagation delay time, HIGH TXD to Driver Recessive	See 图 6-2, S, STB and SHDN = 0V. R _L = 60Ω, C _L = 100pF,		25	ns		
t _{pLD}	Propagation delay time, LOW TXD to Driver Dominant			20			
t _{sk(p)}	Pulse skew (t _{pHR} - t _{pLD})			5			
t _r	Differential output signal rise time			17			
t _f	Differential output signal fall time			9			
t _{TXD_DTO}	Driver dominant time out ⁽¹⁾	See 图 6-8, R _L = 60 Ω , C _L = 100pF		1.2	2.6	3.8	ms
Receiver Switching Characteristics							
t _{pRH}	Propagation delay time, bus recessive input to high RXD output	See 图 6-3, C _{L(RXD)} = 15pF CANL = 1.5V, CANH = 3.5V		62	ns		
t _{pDL}	Propagation delay time, bus dominant input to RXD low output			56			
t _r	Output signal rise time (RXD)			7			
t _f	Output signal fall time (RXD)			6			
t _{RXD_DTO}	Receiver dominant time out ⁽²⁾	See 图 6-10, C _{L(RXD)} = 15pF		1.6	3	5	ms

- (1) The TXD dominant time out (t_{TXD_DTO}) disables the driver of the transceiver once the TXD has been dominant longer than t_{TXD_DTO} , which releases the bus lines to recessive, preventing a local failure from locking the bus dominant. The driver may only transmit dominant again after TXD has been returned HIGH (recessive). While this protects the bus from local faults, locking the bus dominant, it limits the minimum data rate possible. The CAN protocol allows a maximum of eleven successive dominant bits (on TXD) for the worst case, where five successive dominant bits are followed immediately by an error frame. This, along with the t_{TXD_DTO} minimum, limits the minimum bit rate. The minimum bit rate may be calculated by: Minimum Bit Rate = $11 / t_{TXD_DTO} = 11 \text{ bits} / 1.2 \text{ ms} = 9.2 \text{ kbps}$.
- (2) The RXD timeout (t_{RXD_DTO}) disables the RXD output in the case that the bus has been dominant longer than t_{RXD_DTO} , which releases RXD pin to the recessive state (high), thus preventing a dominant bus failure from permanently keeping the RXD pin low. The RXD pin will automatically resume normal operation once the bus has been returned to a recessive state. While this protects the protocol controller from a permanent dominant state, it limits the minimum data rate possible. The CAN protocol allows a maximum of eleven successive dominant bits (on RXD) for the worst case, where five successive dominant bits are followed immediately by an error frame. This, along with the t_{RXD_DTO} minimum, limits the minimum bit rate. The minimum bit rate may be calculated by: Minimum Bit Rate = $11 / t_{RXD_DTO} = 11 \text{ bits} / 1.6 \text{ ms} = 6.9 \text{ kbps}$.

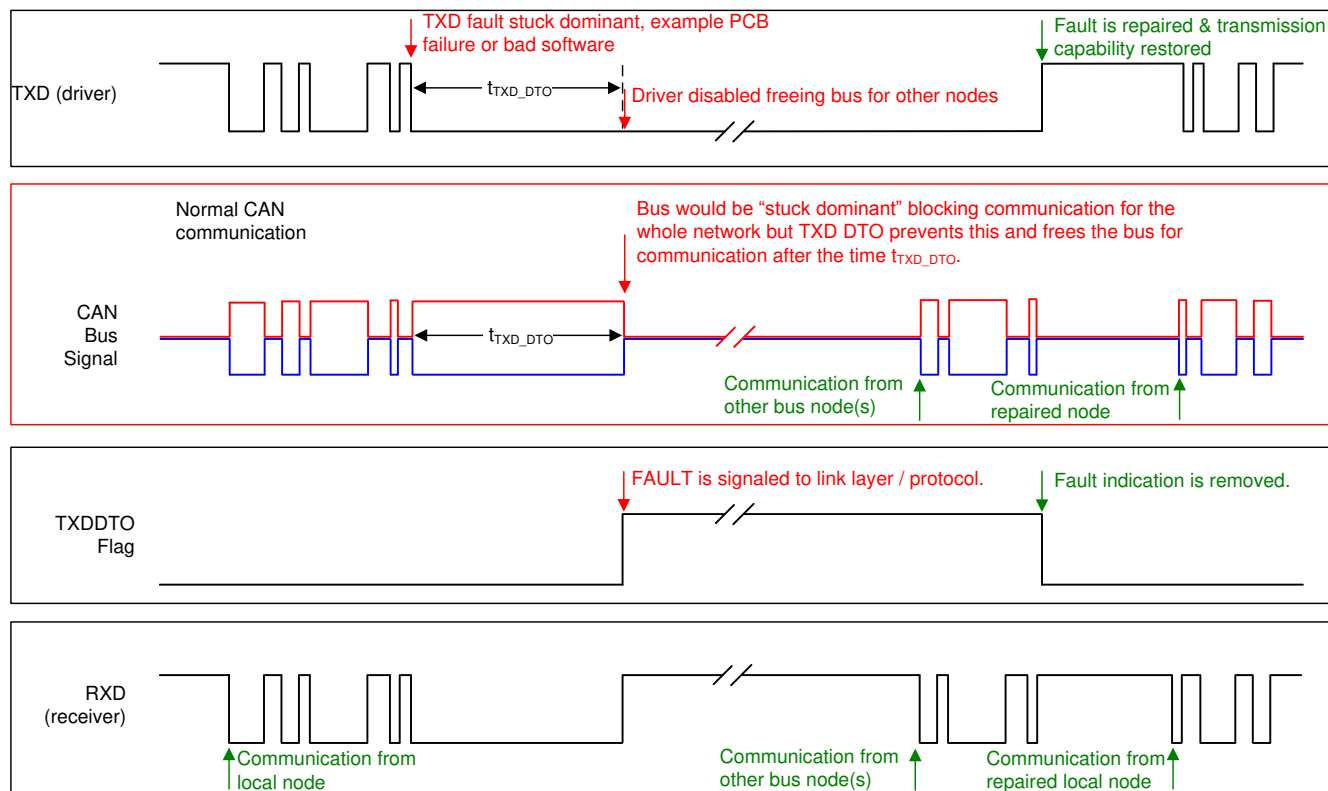


图 5-1. Example Timing Diagram for TXD DTO and FAULT Pin

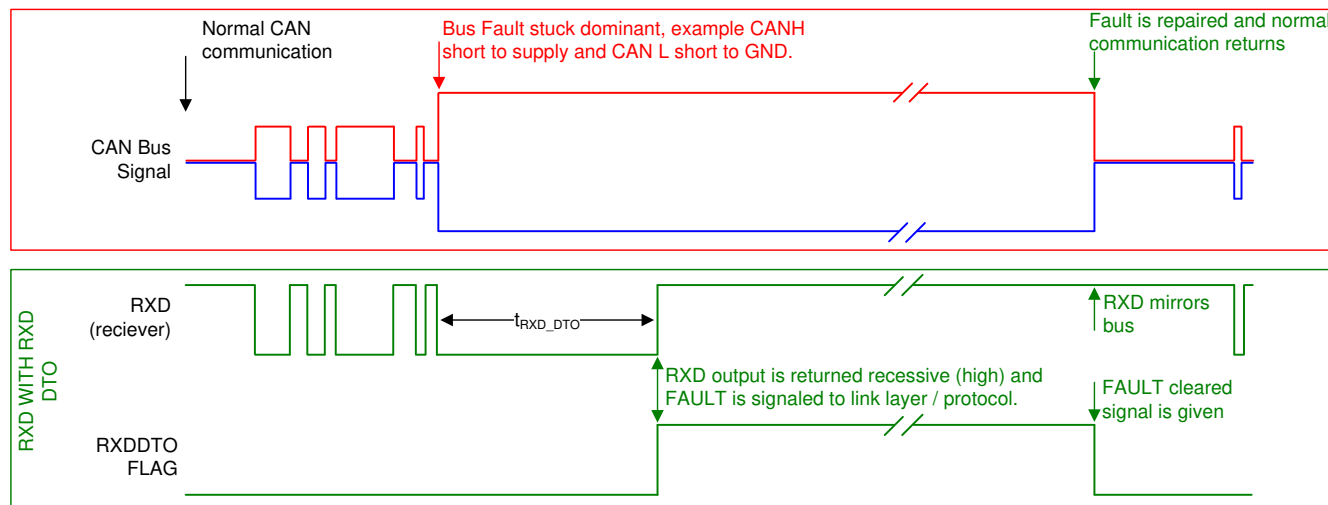


图 5-2. Example Timing Diagram for RXD DTO and FAULT Pin

5.7 Typical Characteristics

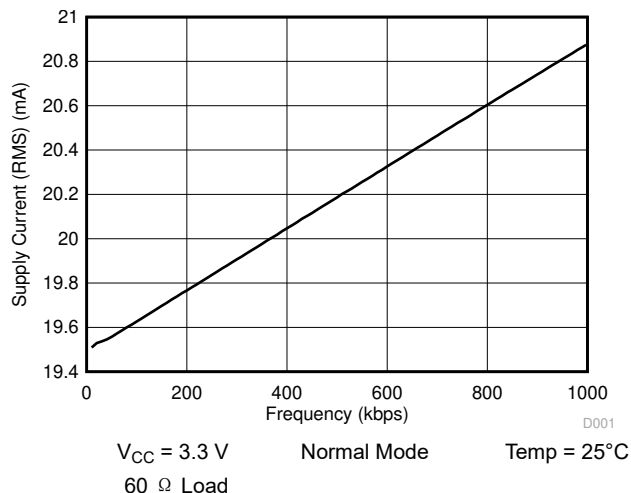


图 5-3. Supply Current (RSM) vs Frequency

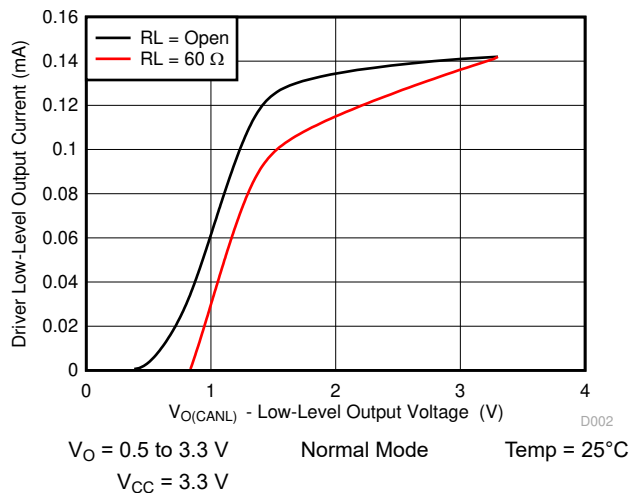


图 5-4. Driver Low-Level Output Current vs Low-level Output Voltage

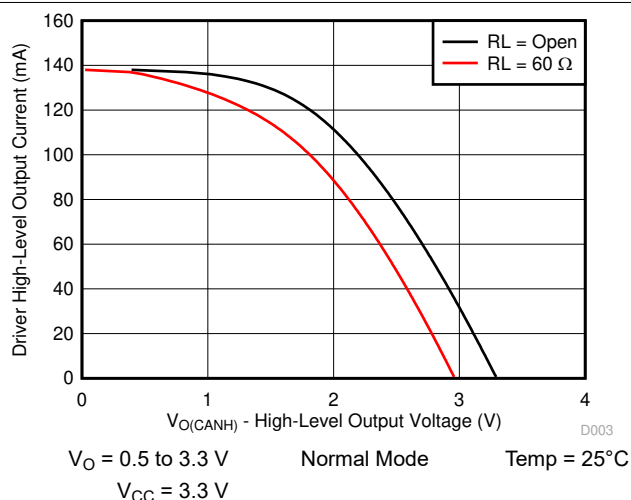


图 5-5. Driver High-Level Output Current vs High-level Output Voltage

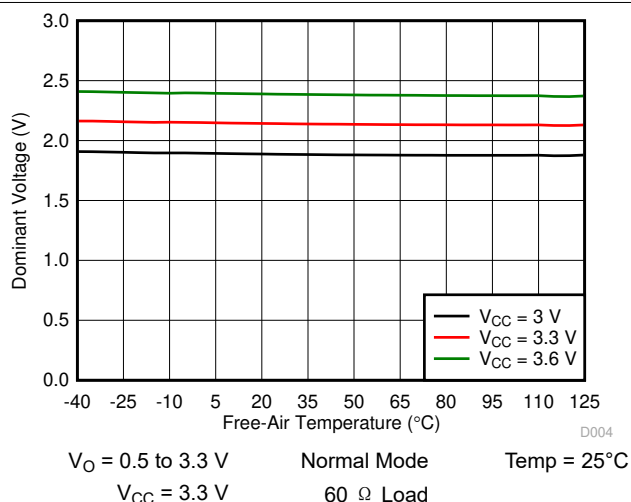


图 5-6. Dominant Voltage (V_{OD}) vs Free-Air Temperature

5.8 Typical Characteristics, TCAN330 Receiver

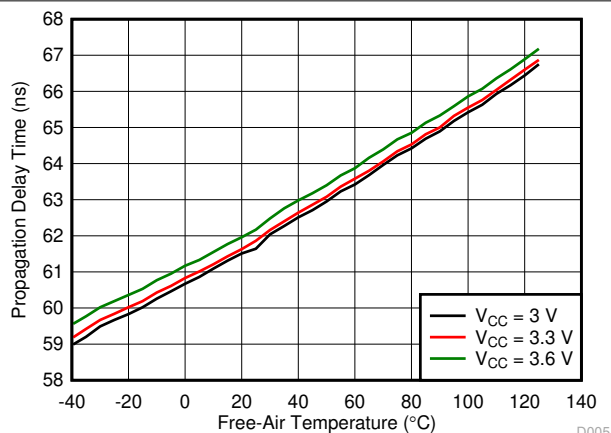


图 5-7. Receiver Bus Recessive Input to High RXD Output Propagation Delay Time vs Free-Air Temperature

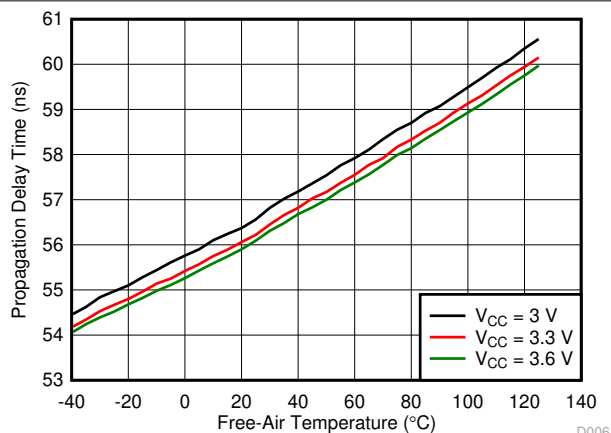


图 5-8. Receiver Bus Dominant Input to Low RXD Output Propagation Delay Time vs Free-Air Temperature

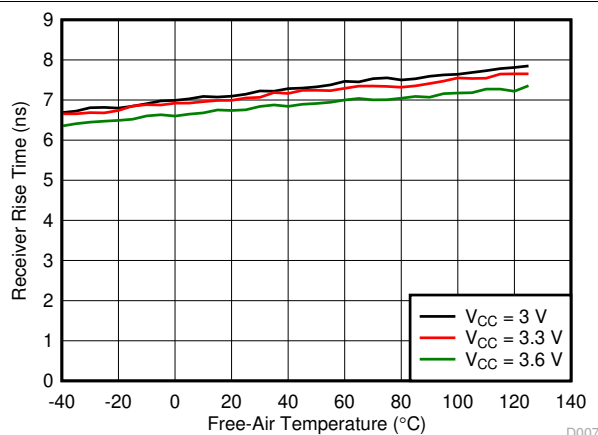


图 5-9. Receiver Rise Time vs Free-Air Temperature

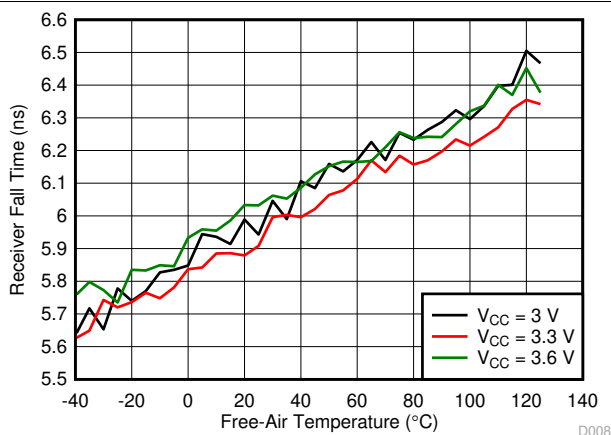


图 5-10. Receiver Fall Time vs Free-Air Temperature

5.9 Typical Characteristics, TCAN330 Driver

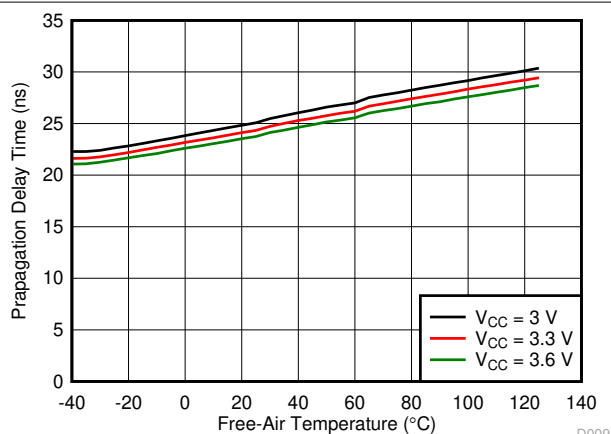


图 5-11. Driver High TXD Input to Driver Recessive Output Propagation Delay Time vs Free-Air Temperature

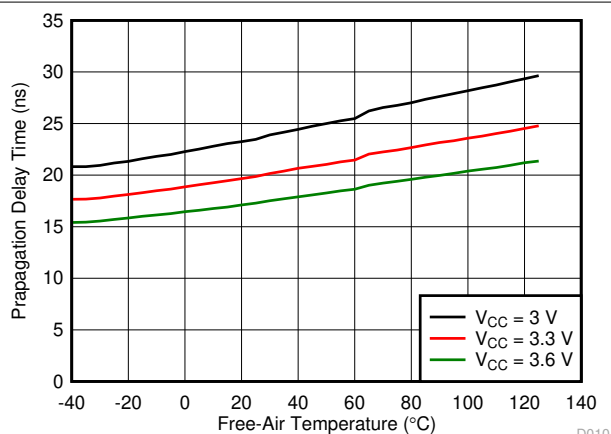


图 5-12. Driver Low TXD Input to Driver Dominant Output Propagation Delay Time vs Free-Air Temperature

5.9 Typical Characteristics, TCAN330 Driver (continued)

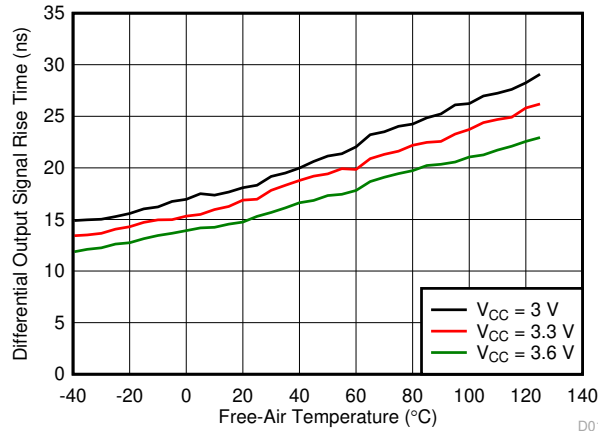


图 5-13. Differential Output Signal Rise Time vs Free-Air Temperature

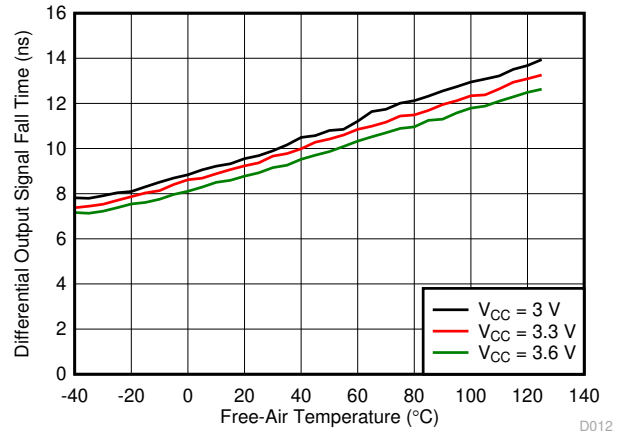


图 5-14. Differential Output Signal Fall Time vs Free-Air Temperature

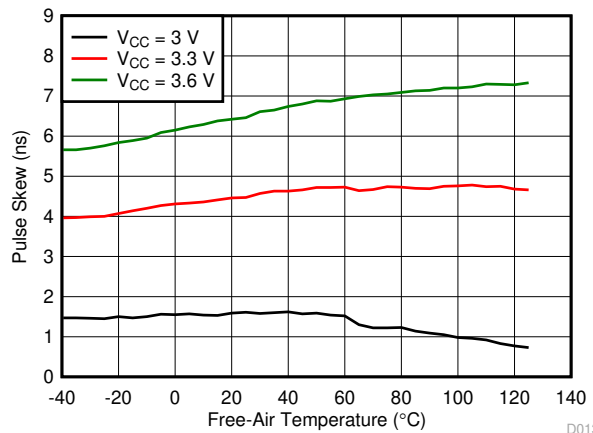


图 5-15. Pulse Skew ($|t_{PHR} - t_{PLD}|$) vs Free-Air Temperature

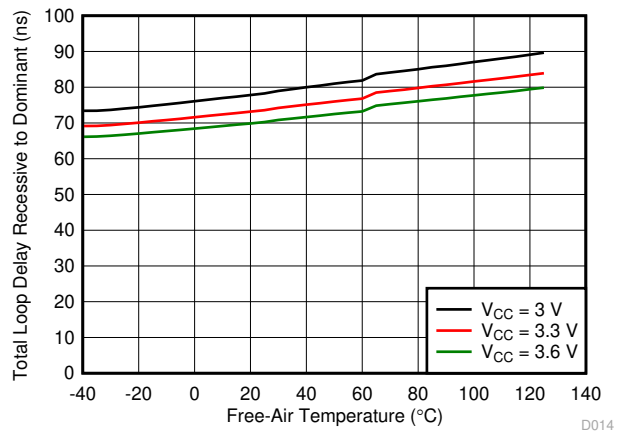


图 5-16. Total Loop Delay Recessive to Dominant $t_{PROP(LOOP1)}$ vs Free-Air Temperature

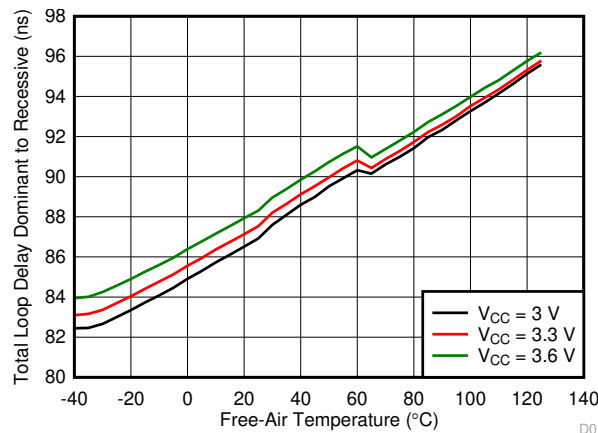


图 5-17. Total Loop Delay Dominant to Recessive $t_{PROP(LOOP2)}$ vs Free-Air Temperature

Parameter Measurement Information

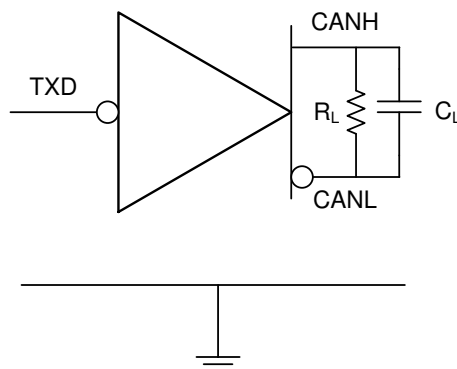


图 6-1. Supply Test Circuit

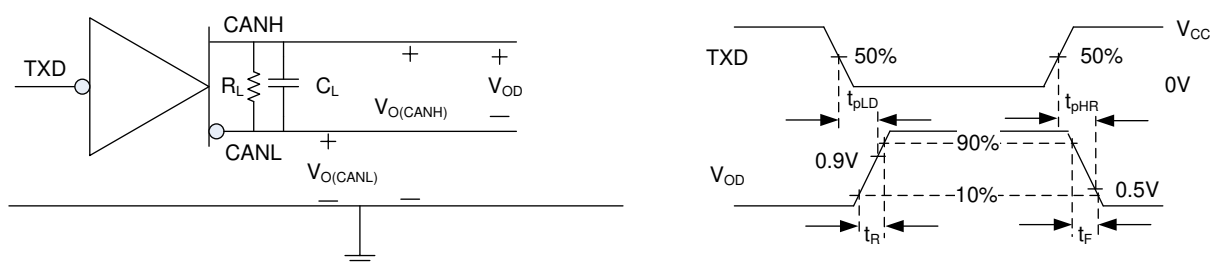


图 6-2. Driver Test Circuit and Measurement

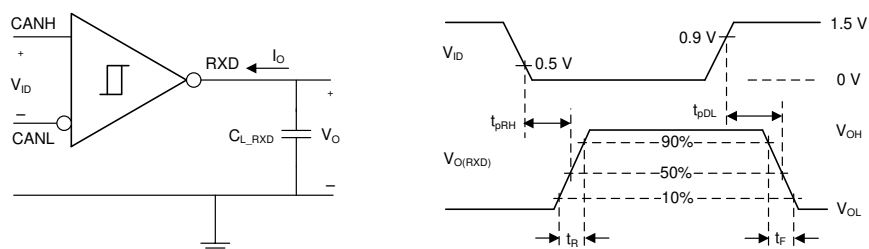


图 6-3. Receiver Test Circuit and Measurement

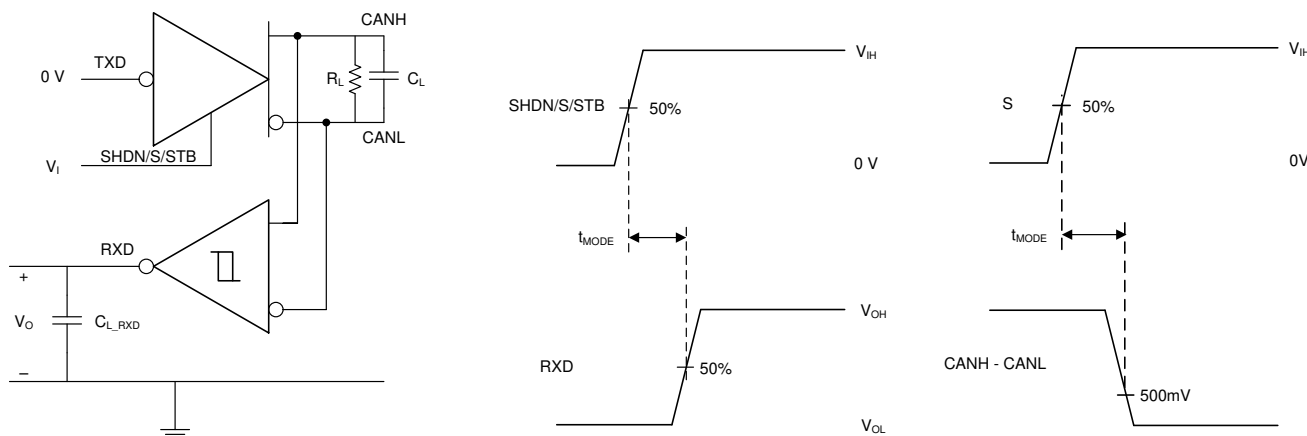


图 6-4. t_{MODE} Test Circuit and Measurement, from Normal to Shutdown, Standby or Silent Mode

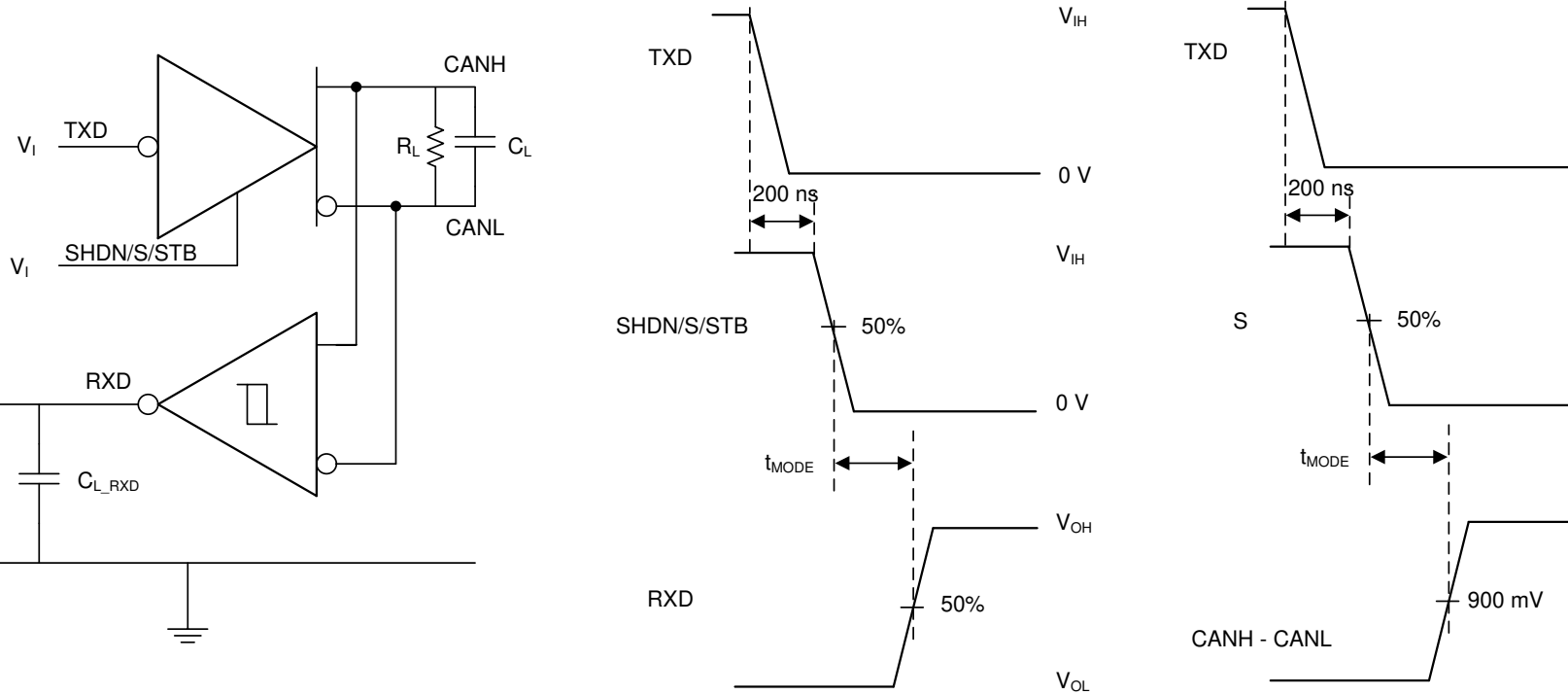


图 6-5. t_{MODE} Test Circuit and Measurement, from Shutdown, Standby or Silent to Normal Mode

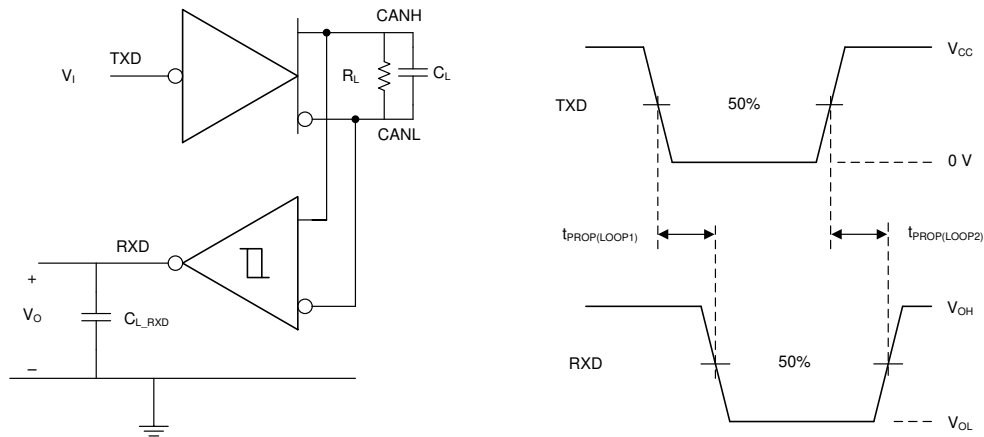


图 6-6. $t_{PROP(LOOP)}$ Test Circuit and Measurement

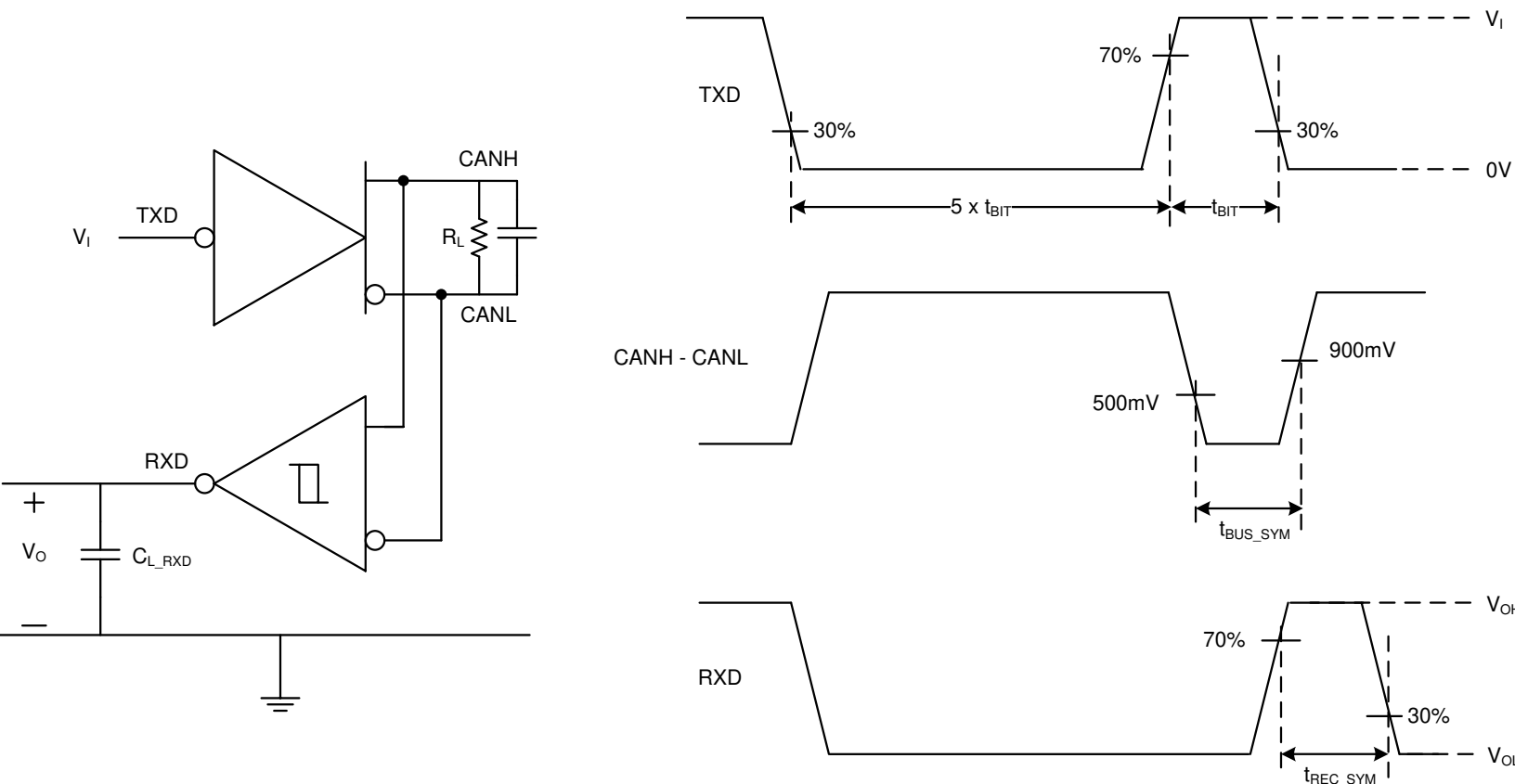


图 6-7. Loop Delay Symmetry Test Circuit and Measurement

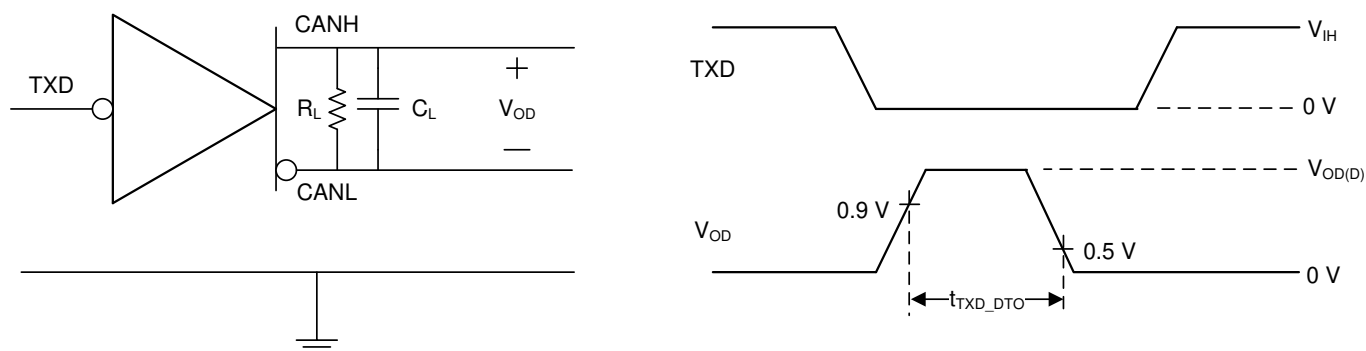


图 6-8. TXD Dominant Time Out Test Circuit and Measurement

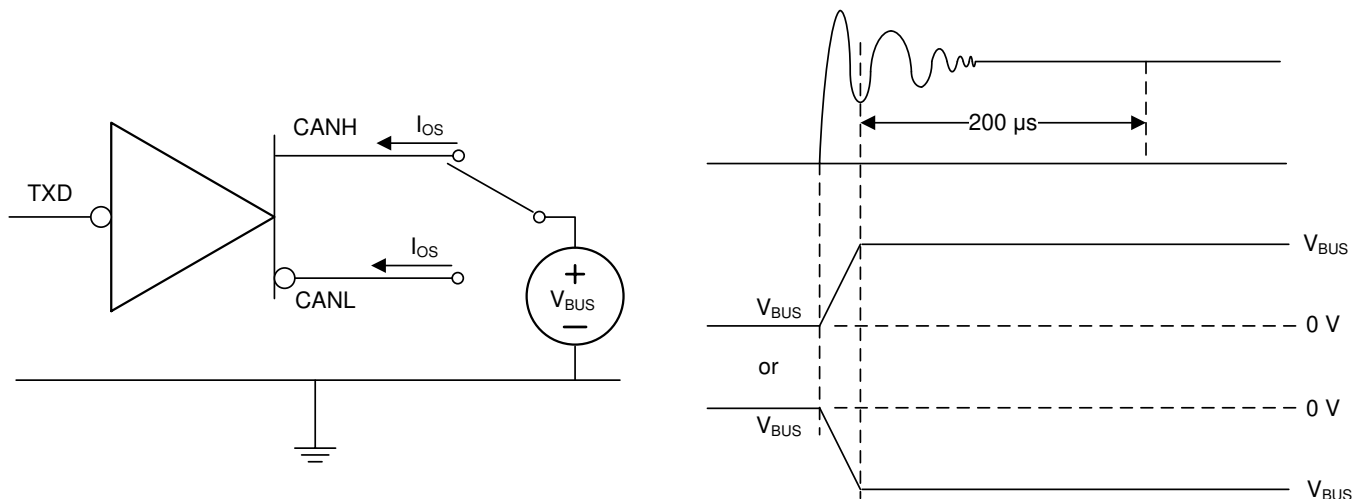


图 6-9. Driver Short-Circuit Current Test and Measurement

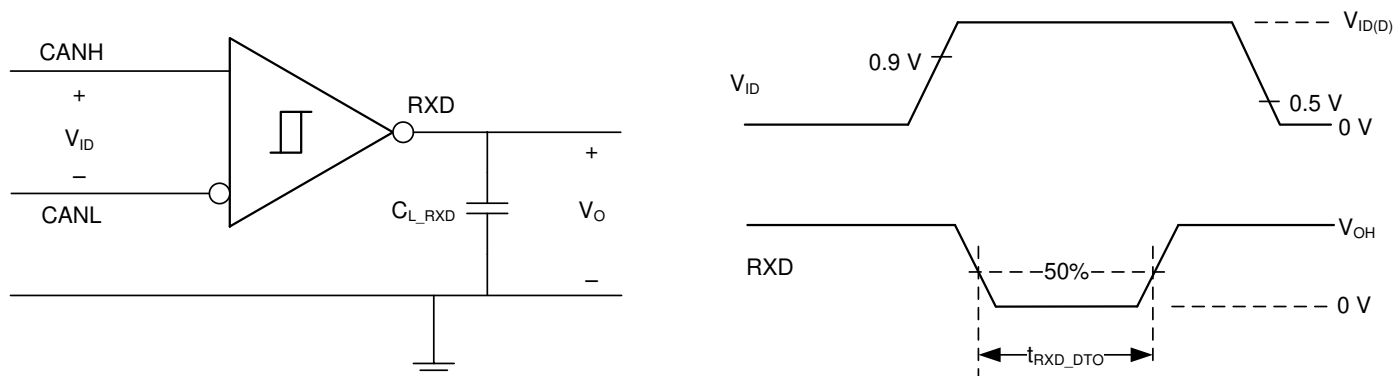


图 6-10. RXD Dominant Timeout Test Circuit and Measurement

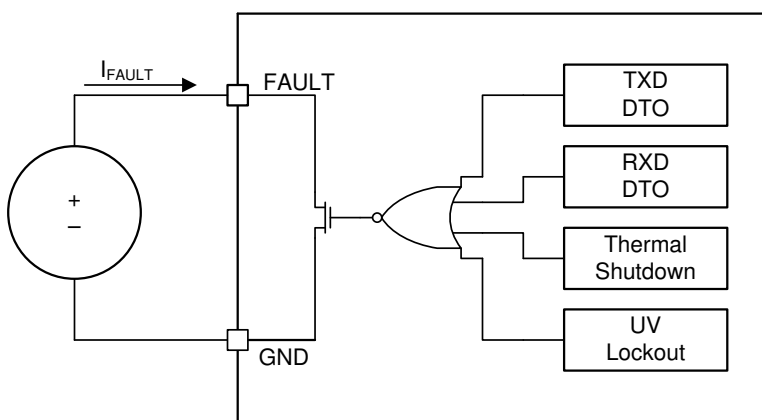


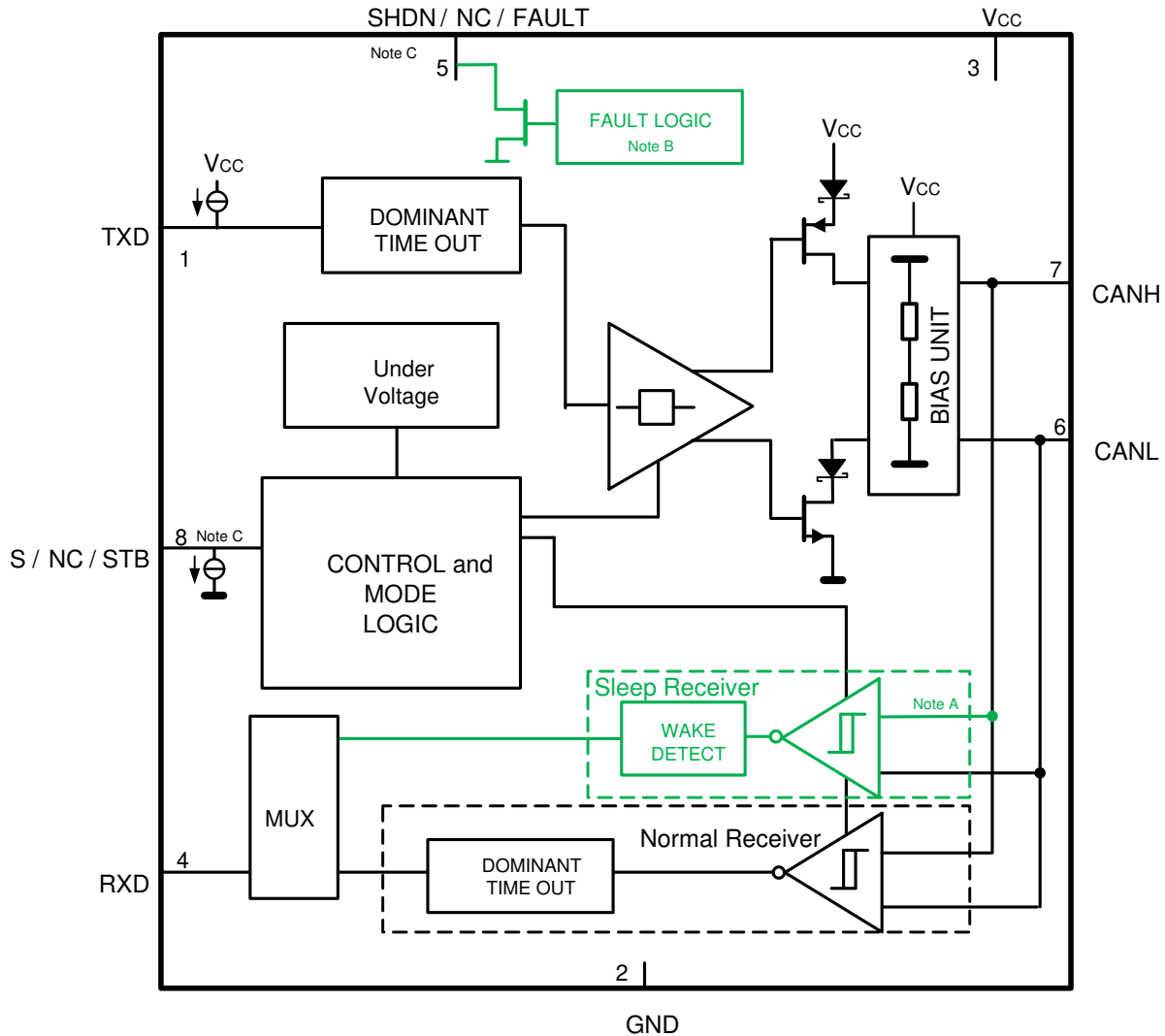
图 6-11. FAULT Test and Measurement

6 Detailed Description

6.1 Overview

This family of CAN transceivers is compatible with the ISO11898-2 High-Speed CAN (controller area network) physical layer standard. The devices are designed to interface between the differential bus lines in CAN and the CAN protocol controller.

6.2 Functional Block Diagram



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- A. Sleep Receiver and Wake Detect are device dependent options and are only available in TCAN334.
- B. Fault Logic is only available in TCAN337.
- C. Pin 5 and 8 functions are device dependent. Refer to [§ Device Options](#).

6.3 Feature Description

6.3.1 TXD Dominant Timeout (TXD DTO)

During normal mode (the only mode where the CAN driver is active), the TXD DTO circuit prevents the transceiver from blocking network communication in the event of a hardware or software failure where TXD is held dominant longer than the timeout period t_{TXD_DTO} . The DTO circuit timer starts on a falling edge on TXD. The DTO circuit disables the CAN bus driver if no rising edge is seen before the timeout period expires. This

frees the bus for communication between other nodes on the network. The CAN driver is re-activated when a recessive signal is seen on TXD pin, thus clearing the TXD DTO condition. The receiver and RXD pin still reflect the CAN bus, and the bus pins are biased to recessive level during a TXD dominant timeout.

6.3.2 RXD Dominant Timeout (RXD DTO)

All devices have a RXD DTO circuit that prevents a bus stuck dominant fault from permanently driving the RXD output dominant (low) when the bus is held dominant longer than the timeout period t_{RXD_DTO} . The RXD DTO timer starts on a falling edge on RXD (bus going dominant). If no rising edge (bus returning recessive) is seen before the timeout constant of the circuit expires (t_{RXD_DTO}), the RXD pin returns high (recessive). The RXD output is re-activated to mirror the bus receiver output when a recessive signal is seen on the bus, clearing the RXD dominant timeout. The CAN bus pins are biased to the recessive level during a RXD DTO.

6.3.3 Thermal Shutdown

If the junction temperature of the device exceeds the thermal shutdown threshold, the device turns off the CAN driver circuits thus blocking the TXD-to-bus transmission path. The shutdown condition is cleared when the junction temperature of the device drops below the thermal shutdown temperature of the device. If the fault condition that caused the thermal shutdown is still present, the temperature may rise again and the device will enter thermal shut down again. Prolonged operation with thermal shutdown conditions may affect device reliability. The thermal shutdown circuit includes hysteresis to avoid oscillation of the driver output.

During thermal shutdown the CAN bus drivers are turned off, thus no transmission is possible from TXD to the bus. The CAN bus pins are biased to recessive level during a thermal shutdown and the receiver to RXD path remains operational.

6.3.4 Undervoltage Lockout and Unpowered Device

The V_{CC} supply terminal has under voltage detection which will place the device in protected mode if the supply drops below the UVLO threshold. This protects the bus during an under voltage event on V_{CC} by placing the bus into a high impedance biased to ground state and the RXD terminal into a tri-stated (high impedance) state. During undervoltage the device does not pass any signals from the bus. If the device is in normal mode and V_{CC} supply is lost the device will transition to a protected mode.

The device is designed to be an "ideal passive" or "no load" to the CAN bus if the device is unpowered. The bus terminals (CANH, CANL) have low leakage currents when the device is unpowered, so the device does not load the bus. This is critical if some nodes of the network are unpowered while the rest of the of network remains operational. Logic pins also have low leakage currents when the device is unpowered, so the device does not load other circuits which may remain powered.

表 6-1. Undervoltage Protection 3.3-V Single Supply Devices

V_{CC}	DEVICE STATE	BUS	RXD
GOOD	Operational	Per Operating Mode	Per Operating Mode
BAD	Protected	Common mode bias to GND	High Impedance
UNPOWERED	Unpowered	High Impedance (no load)	High Impedance

6.3.5 Fault Pin (TCAN337)

If one or more of the faults (TXD-Dominant Timeout, RXD dominant Timeout, Thermal Shutdown or Undervoltage Lockout) occurs, the FAULT pin (open-drain) turns off, resulting in a high level when externally pulled up to V_{CC} supply.

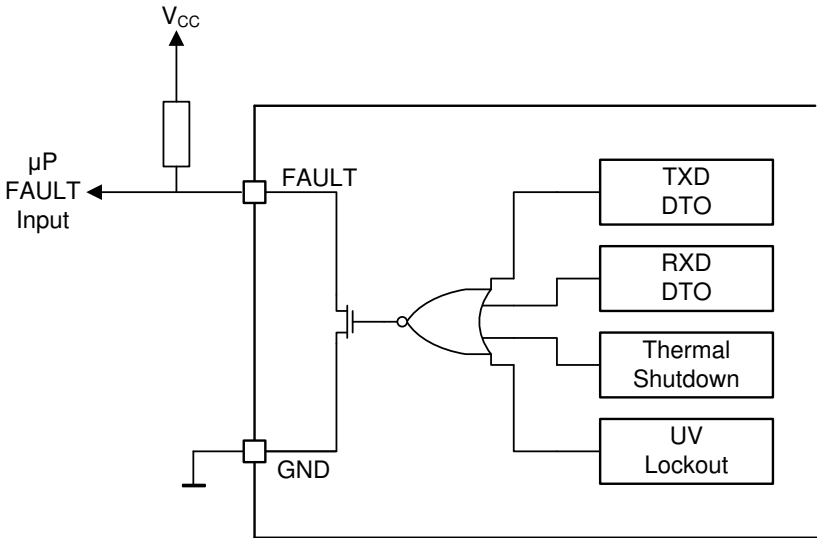


图 6-1. FAULT Pin Function Diagram and Application

6.3.6 Floating Pins

The device has internal pull ups and pull downs on critical terminals to place the device into known states if the pin floats. See 表 6-1 for details on pin bias conditions.

表 6-2. Pin Bias

PIN	PULL UP or PULL DOWN	COMMENT
TXD	Pull up	Weakly biases TXD toward recessive to prevent bus blockage or TXD DTO triggering.
STB	Pull down	Weakly biases STB terminal towards normal mode.
S	Pull down	Weakly biases S terminal towards normal mode.
SHDN	Pull down	Weakly biases SHDN terminal towards normal mode.

The internal bias should not be relied on by design, especially in noisy environments, but should be considered a fall back protection. Special care needs to be taken when the device is used with MCUs using open drain outputs. TXD is weakly internally pulled up. The TXD pull up strength and CAN bit timing require special consideration when this device is used with an open drain TXD output on the microprocessor's CAN controller. An adequate external pull up resistor must be used to ensure that the TXD output of the microprocessor maintains adequate bit timing input to the CAN transceiver.

6.3.7 CAN Bus Short Circuit Current Limiting

The device has several protection features that limit the short circuit current when a CAN bus line is shorted. These include CAN driver current limiting (dominant and recessive). The device has TXD dominant time out which prevents permanently having the higher short circuit current of dominant state in case of a system fault. During CAN communication the bus switches between dominant and recessive states, thus the short circuit current may be viewed either as the current during each bus state or as a DC average current. For system current and power considerations in the termination resistors and common mode choke ratings the average short circuit current should be used. The percentage dominant is limited by the TXD dominant time out and CAN protocol which has forced state changes and recessive bits such as bit stuffing, control fields, and interframe

space. These ensure there is a minimum recessive amount of time on the bus even if the data field contains a high percentage of dominant bits.

The short circuit current of the bus depends on the ratio of recessive to dominant bits and their respective short circuit currents. The average short circuit current may be calculated with the following formula:

$$I_{OS(AVG)} = \%Transmit \times [(\%REC_Bits \times I_{OS(SS)_REC}) + (\%DOM_Bits \times I_{OS(SS)_DOM})] + [\%Receive \times I_{OS(SS)_REC}] \quad (1)$$

Where:

- $I_{OS(AVG)}$ is the average short circuit current
- $\%Transmit$ is the percentage the node is transmitting CAN messages
- $\%Receive$ is the percentage the node is receiving CAN messages
- $\%REC_Bits$ is the percentage of recessive bits in the transmitted CAN messages
- $\%DOM_Bits$ is the percentage of dominant bits in the transmitted CAN messages
- $I_{OS(SS)_REC}$ is the recessive steady state short circuit current
- $I_{OS(SS)_DOM}$ is the dominant steady state short circuit current

The short circuit current and possible fault cases of the network should be taken into consideration when sizing the power ratings of the termination resistance and other network components.

6.3.8 ESD Protection

The bus pins of the TCAN33x family possess on-chip ESD protection against $\pm 25\text{kV}$ human body model (HBM) and $\pm 12\text{kV}$ IEC61000-4-2 contact discharge. The IEC-ESD test is far more severe than the HBM-ESD test. The 50% higher charge capacitance, C_S , and 78% lower discharge resistance, R_D of the IEC model produce significantly higher discharge currents than the HBM-model.

As stated in the IEC 61000-4-2 standard, contact discharge is the preferred test method; although IEC air-gap testing is less repeatable than contact testing, air discharge protection levels are inferred from the contact discharge test results.

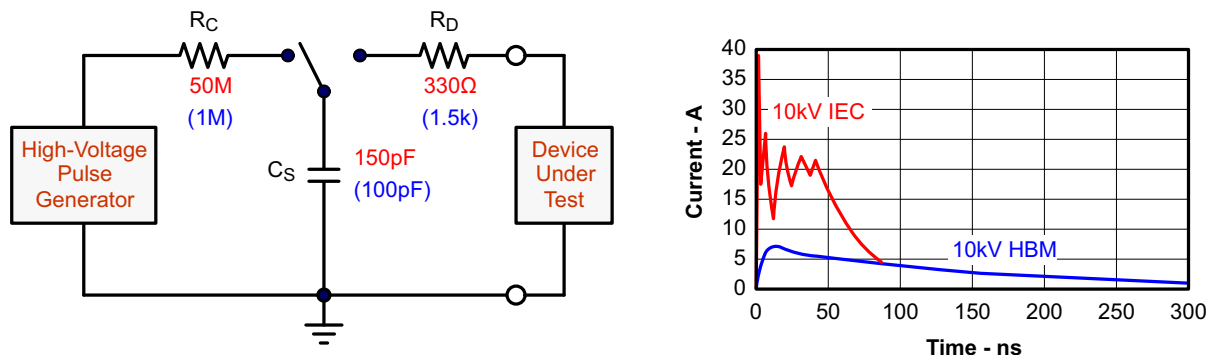


图 6-2. HBM and IEC-ESD Models and Currents in Comparison (HBM Values in Parenthesis)

6.3.9 Digital Inputs and Outputs

All the devices in this family are single 3.3V nominal supply devices. The digital logic input and output levels for these devices have TTL threshold levels.

6.4 Device Functional Modes

6.4.1 CAN Bus States

The CAN bus has two logical states during operation: recessive and dominant. See 图 6-3 and 图 6-4.

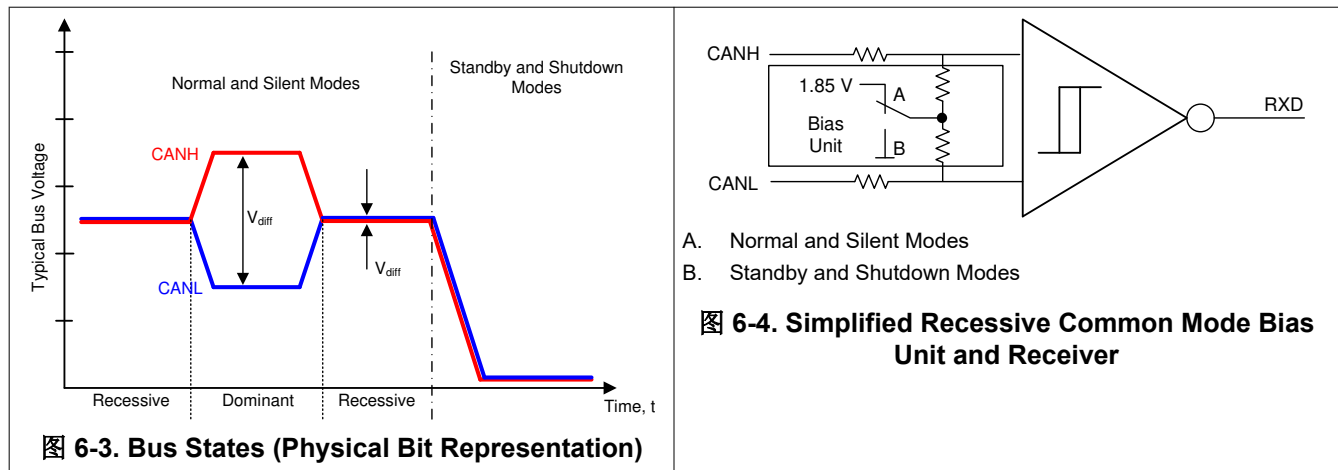
Recessive bus state is when the high resistive internal input resistors of each node receiver bias the bus to a common mode of about 1.85V across the bus termination resistors. Recessive is equivalent to logic high and is typically a differential voltage on the bus of about 0V. Recessive state is also the idle state.

Dominant bus state is when the bus is driven differentially by one or more drivers. Current is induced to flow through the termination resistors and generate a differential voltage on the bus. Dominant is equivalent to logic low and is a differential voltage on the bus greater than the minimum threshold for a CAN dominant. A dominant state overwrites the recessive state.

During arbitration, multiple CAN nodes may transmit a dominant bit at the same time. In this case, the differential voltage of the bus is greater than the differential voltage of a single driver.

The host microprocessor of the CAN node uses the TXD terminal to drive the bus, and receives data from the bus on the RXD pin.

Transceivers with low power Standby Mode have a third bus state where the bus terminals are weakly biased to ground via the high resistance internal resistors of the receiver. See 图 6-3 and 图 6-4.



The devices have four main operating modes:

1. Normal mode (all devices)
2. Silent mode (TCAN330, TCAN337)
3. Standby mode with wake (TCAN334)
4. Shutdown mode (TCAN330, TCAN334)

表 6-3. CAN Transceivers with Silent Mode

S	Device MODE	DRIVER	RECEIVER	RXD PIN
HIGH	Reduced Power Silent (Listen) Mode	Disabled (OFF) ⁽²⁾	Enabled (ON)	Mirrors Bus State ⁽¹⁾
LOW/NC	Normal Mode	Enabled (ON)	Enabled (ON)	

(1) Mirrors bus state: low if CAN bus is dominant, high if CAN bus is recessive.

(2) See 图 6-3 for bus state.

表 6-4. CAN Transceivers with Standby Mode with Wake

STB	Device MODE	DRIVER	RECEIVER	RXD Terminal
HIGH	Ultra Low Current Standby Mode	Disabled (OFF) ⁽²⁾	Low Power Receiver and Bus Monitor Enabled (ON)	High (Recessive) until WUP, then filtered mirrors of Bus State ⁽¹⁾
LOW/NC	Normal Mode	Enabled (ON)	Enabled (ON)	Mirrors Bus State ⁽¹⁾

(1) Standby Mode RXD behavior: See 图 6-5.

表 6-5. CAN Transceivers with Shutdown Mode

SHDN	Device MODE	DRIVER	RECEIVER	RXD Terminal
HIGH	Lowest Current	Disabled (OFF) ⁽²⁾	Disabled (OFF)	High (Recessive)
LOW/NC	Normal Mode	Enabled (ON)	Enabled (ON)	Mirrors Bus State ⁽¹⁾

6.4.2 Normal Mode

This is the normal operating mode of the device. The CAN driver and receiver are fully operational and CAN communication is bi-directional. The driver is translating a digital input on TXD to a differential output on CANH and CANL. The receiver is translating the differential signal from CANH and CANL to a digital output on RXD.

6.4.3 Silent Mode

This is the silent or receive only mode of the device. The CAN driver is disabled but the receiver is fully operational. CAN communication is unidirectional and only flows from the CAN bus through the receive path of the transceiver to the CAN protocol controller via the RXD output pin. The receiver is translating the differential signal from CANH and CANL to a digital output on RXD.

6.4.4 Standby Mode with Wake

This is the low power mode of the device. The CAN driver and main receiver are turned off and bi-directional CAN communication is not possible. The low power receiver and bus monitor are enabled to allow for RXD Wake Requests via the CAN bus. A wake up request will be output to RXD (driven low) as shown in 图 6-5. The local CAN protocol microprocessor should monitor RXD for transitions (high to low) and reactivate the device to normal mode based on the RXD Wake Request. The CAN bus pins are weakly pulled to GND during this mode, see 图 6-4.

6.4.5 Bus Wake via RXD Request (BWRR) in Standby Mode

The TCAN334 with low power standby mode, offers a wake up from the CAN bus mechanism called bus wake via RXD Request (BWRR) to indicate to a host microprocessor that the bus is active and it should wake up and return to normal CAN communication.

This device uses the multiple filtered dominant wake-up pattern (WUP) from ISO11898-5 to qualify bus traffic into a request to wake the host microprocessor. The bus wake request is signaled to the microprocessor by a falling edge and low corresponding to a “filtered” bus dominant on the RXD terminal (BWRR).

The wake up pattern (WUP) consists of a filtered dominant bus, then a filtered recessive bus time followed by a second filtered bus time. Once the WUP is detected the device will start issuing wake up requests (BWRR) on the RXD terminal every time a filtered dominant time is received from the bus. The first filtered dominant initiates the WUP and the bus monitor waits on a filtered recessive; other bus traffic does not reset the bus monitor. Once a filtered recessive is received, the bus monitor waits on a filtered dominant and again; other bus traffic does not reset the bus monitor. Immediately upon receiving of the second filtered dominant, the bus monitor recognizes the WUP and transitions to BWRR mode. In this mode, RXD is driven low for all dominant bits lasting for longer than t_{WK_FILTER} . The RXD output during BWRR matches the classical 8-pin CAN devices, such as the TCANA1040A-Q1 device, that used the single filtered dominant on the bus as the wake up request mechanism from ISO11898-5.

For a dominant or recessive to be considered *filtered*, the bus must be in that state for more than t_{WK_FILTER} time. Due to variability in the t_{WK_FILTER} the following scenarios are applicable. Bus state times less than

$t_{WK_FILTER(MIN)}$ are never detected as part of a WUP and thus no BWRR is generated. Bus state times between $t_{WK_FILTER(MIN)}$ and $t_{WK_FILTER(MAX)}$ may be detected as part of a WUP and a BWRR may be generated. Bus state times more than $t_{WK_FILTER(MAX)}$ are always detected as part of a WUP and thus a BWRR is always generated.

See [图 6-5](#) for the timing diagram of the WUP. The pattern, t_{WK_FILTER} time used for the WUP and BWRR prevent noise and bus stuck dominant faults from causing false wake requests. If the device is switched to normal mode, or an under voltage event occurs on V_{CC} the BWRR will be lost.

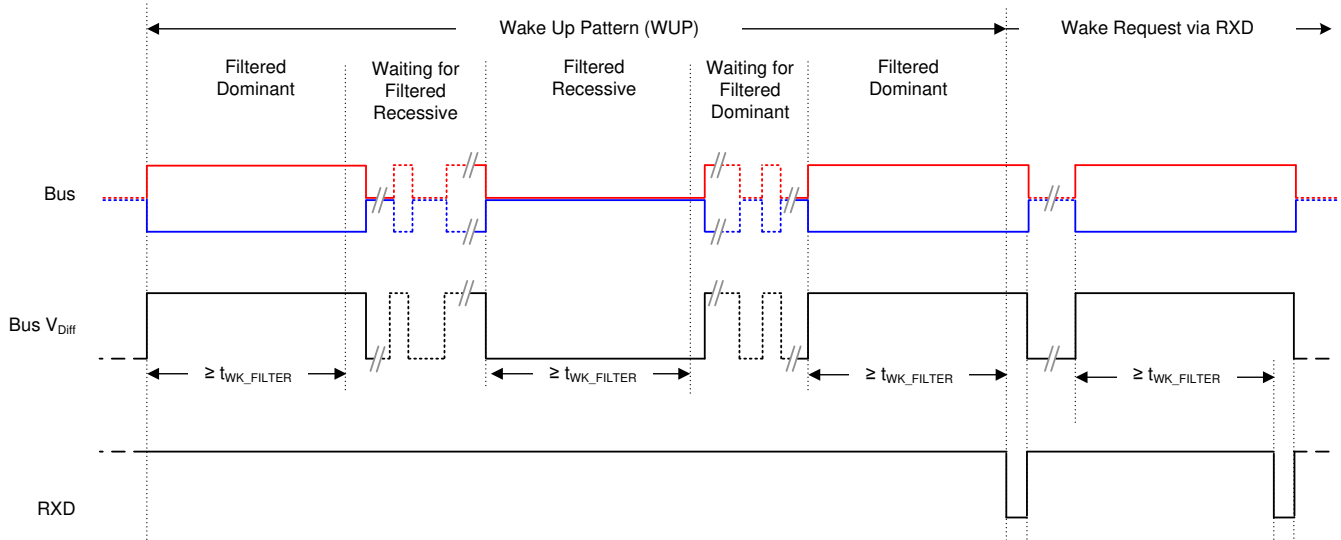


图 6-5. Wake Up Pattern (WUP) and Bus Wake via RXD Request (BWRR)

6.4.6 Shutdown Mode

This is the lowest power mode of all of the devices. The CAN driver and receiver are turned off and bi-directional CAN communication is not possible. It is not possible to receive a remote wake request via the CAN bus in this mode. The CAN bus pins are pulled to GND during this mode as shown in [图 6-3](#).

6.4.7 Driver and Receiver Function Tables

表 6-6. Driver Function Table

DEVICE MODE	TXD ⁽¹⁾ INPUT	BUS OUTPUTS ⁽²⁾		DRIVEN BUS STATE ⁽³⁾
		CANH	CANL	
Normal	L	H	L	Dominant
	H or Open	Z	Z	Biased Recessive
Silent	X	Z	Z	Biased Recessive
Standby	X	Z	Z	Weak Pull to GND
Shutdown	X	Z	Z	Weak Pull to GND

(1) H = high level, L = low level, X = irrelevant.

(2) H = high level, L = low level, Z = high Z receiver bias.

(3) For Bus state and bias see 图 6-3 and 图 6-4.

表 6-7. Receiver Function Table Normal and Standby Modes

DEVICE MODE	CAN DIFFERENTIAL INPUTS $V_{(ID)} = V_{(CANH)} - V_{(CANL)}$	BUS STATE	RXD PIN ⁽¹⁾
Normal or Silent	$V_{(ID)} \geq 0.9V$	Dominant	L
	$0.5V < V_{(ID)} < 0.9V$	?	?
	$V_{(ID)} \leq 0.5V$	Recessive	H
Standby	$V_{(ID)} \geq 1.15V$	Dominant	See 图 6-5
	$0.4V < V_{(ID)} < 1.15V$	?	
	$V_{(ID)} \leq 0.4V$	Recessive	
Shutdown	Any	Recessive	H
Any	Open ($V_{(ID)} \approx 0V$)	Open	H

(1) I = high level, L = low level, ? = indeterminate.

7 Application Information Disclaimer

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

7.1 Application Information

7.1.1 Bus Loading, Length and Number of Nodes

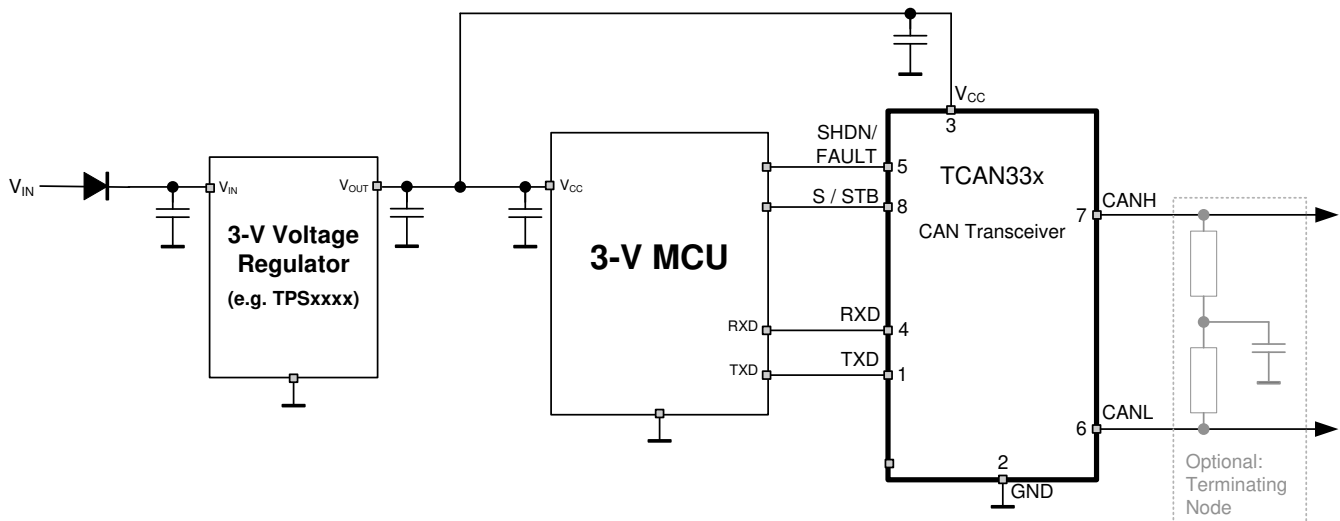
The ISO 11898 standard specifies a data rate up to 1Mbps, maximum CAN bus cable length of 40m, maximum drop line (stub) length of 0.3m and a maximum of 30 nodes. However, with careful network design, the system may have longer cables, longer stub lengths, and many more nodes to a bus. Many CAN organizations and standards have scaled the use of CAN for applications outside the original ISO 11898 standard. They have made system level trade-offs for data rate, cable length, and parasitic loading of the bus. Examples of some of these specifications are ARINC825, CANopen, CAN Kingdom, DeviceNet and NMEA200.

A high number of nodes requires a transceiver with high input impedance and wide common mode range such as the TCAN33x CAN family. ISO 11898-2 specifies the driver differential output with a 60Ω load (two 120Ω termination resistors in parallel) and the differential output must be greater than 1.5V. The TCAN33x devices are specified to meet the 1.5V requirement with a 50Ω load across a common mode range of -12V to 12V through a 330Ω coupling network. This network represents the bus loading of 120 TCAN33x transceivers based on their minimum differential input resistance of $40\text{k}\Omega$.

For CAN network design, margin must be given for signal loss across the system and cabling, parasitic loadings, network imbalances, ground offsets and signal integrity, thus a practical maximum number of nodes may be lower. Bus length may also be extended beyond the original ISO 11898 standard of 40m by careful system design and data rate tradeoffs. For example, CANopen network design guidelines allow the network to be up to 1km with changes in the termination resistance, cabling, number of nodes and data rate.

This flexibility in CAN network design is one of the key strengths of the various extensions and additional standards that have been built on the original ISO 11898 CAN standard.

7.2 Typical Application



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图 7-1. Typical 3.3V Application

7.2.1 Design Requirements

7.2.1.1 CAN Termination

The ISO 11898 standard specifies the interconnect to be a twisted-pair cable (shielded or unshielded) with $120\ \Omega$ characteristic impedance (Z_0). Resistors equal to the characteristic impedance of the line should be used to terminate both ends of the cable to prevent signal reflections. Unterminated drop lines (stubs) connecting nodes to the bus should be kept as short as possible to minimize signal reflections. The termination may be on the cable or in a node, but if nodes may be removed from the bus the termination must be carefully placed so that it is not removed from the bus.

7.2.2 Detailed Design Procedure

Termination is typically a $120\ \Omega$ resistor at each end of the bus. If filtering and stabilization of the common mode voltage of the bus is desired, then split termination may be used. Split termination uses two $60\ \Omega$ resistors with a capacitor in the middle of these resistors to ground. Split termination improves the electromagnetic emissions behavior of the network by eliminating fluctuations in the bus common mode voltages at the start and end of message transmissions.

Care should be taken in the power ratings of the termination resistors used. Typically the worst case condition would be if the system power supply was shorted across the termination resistance to ground. In most cases, the current flow through the resistor in this condition is much higher than the transceiver current limit.

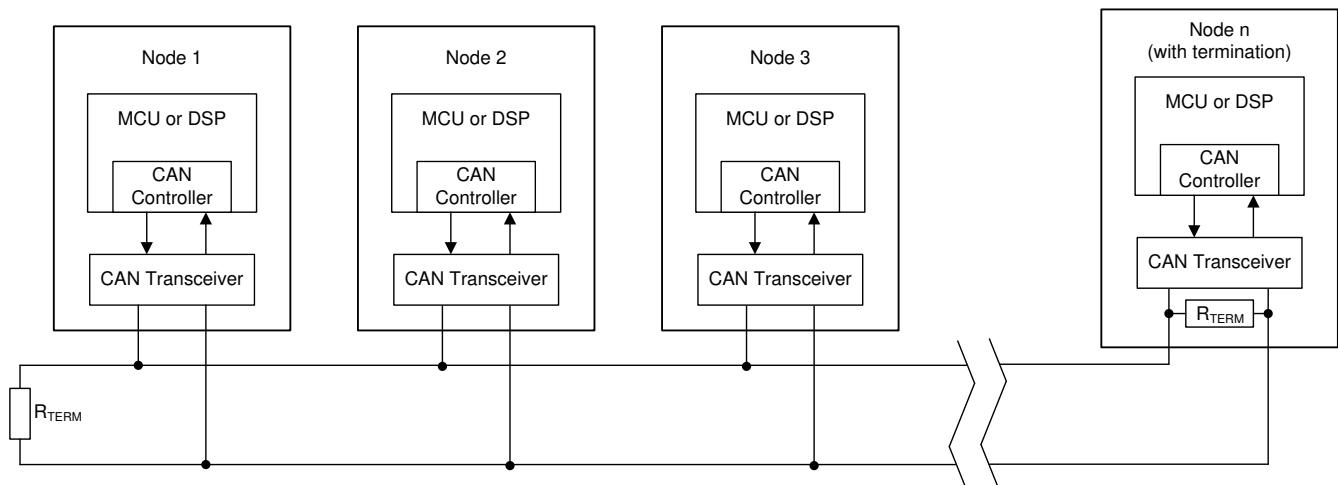


图 7-2. Typical CAN Bus

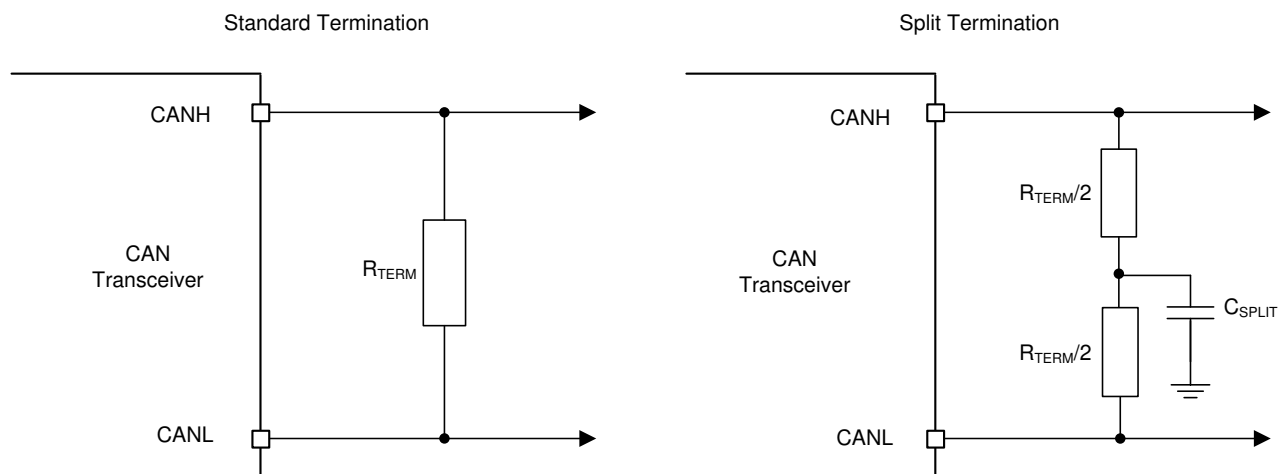
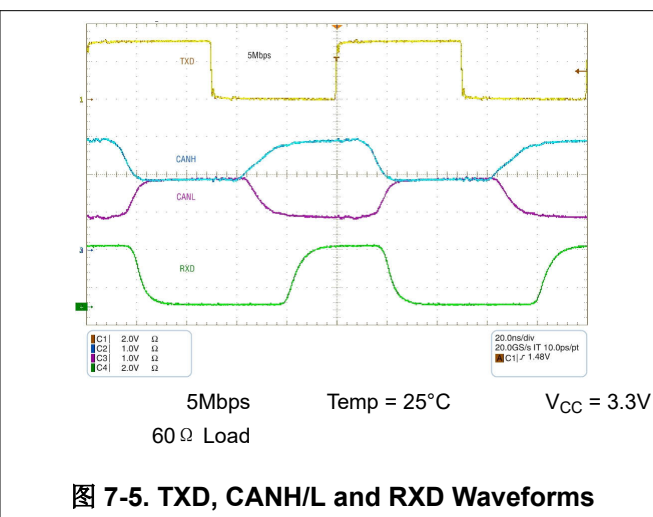
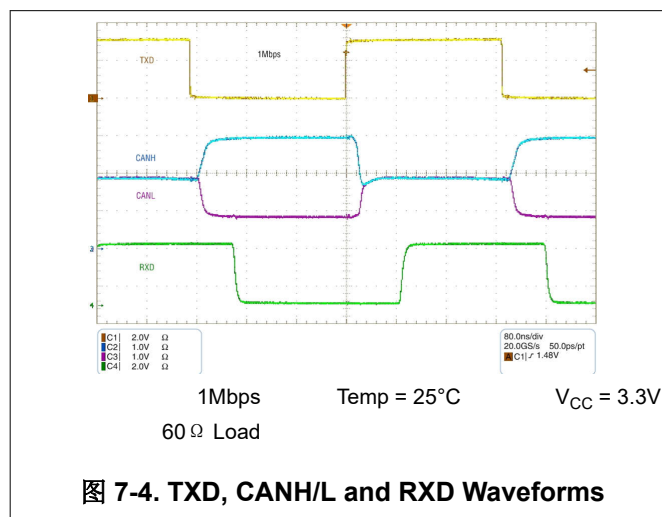


图 7-3. CAN Bus Termination Concepts

7.2.3 Application Curves



7.3 System Examples

7.3.1 ISO11898 Compliance of TCAN33x Family of 3.3V CAN Transceivers Introduction

Many users value the low power consumption of operating their CAN transceivers from a 3.3V supply. However, some are concerned about the interoperability with 5V supplied transceivers on the same bus. This report analyzes this situation to address those concerns.

7.3.2 Differential Signal

CAN is a differential bus where complementary signals are sent over two wires and the voltage difference between the two wires defines the logical state of the bus. The differential CAN receiver monitors this voltage difference and outputs the bus state with a single ended logic level output signal.

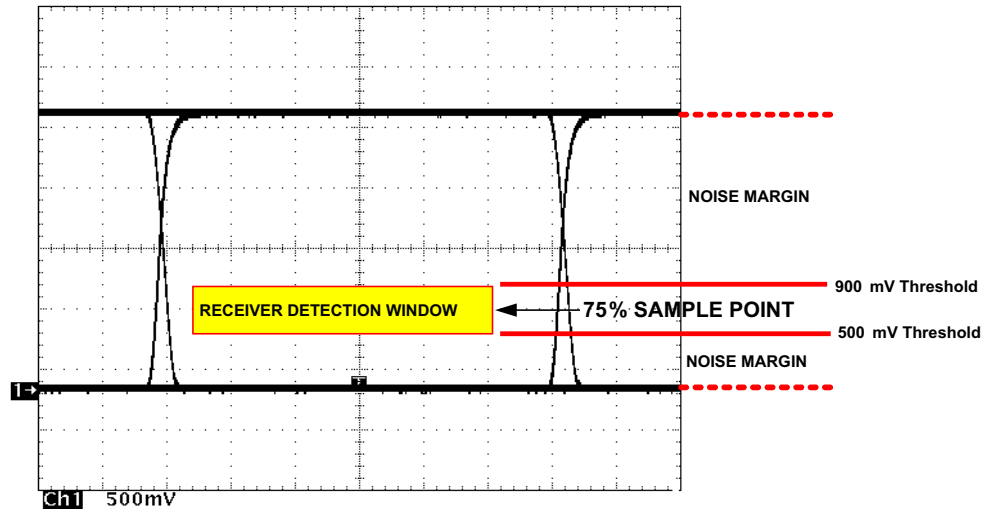


图 7-6. Typical Differential Output Waveform

The CAN driver creates the differential voltage between CANH and CANL in the dominant state. The dominant differential output of the TCAN33x is greater than 1.5V and less than 3V across a 60 Ω load as defined by the ISO11898 standard. These are the same limiting values for 5V supplied CAN transceivers. The bus termination resistors drive the recessive bus state and not the CAN driver.

A CAN receiver is required to output a recessive state when less than 500 mV of differential voltage exists on the bus, and a dominant state when more than 900mV of differential voltage exists on the bus. The CAN receiver must do this with common-mode input voltages from - 2V to 7V. The TCAN33x family receivers meet these same input specifications as 5V supplied receivers.

7.3.3 Common-Mode Signal and EMC Performance

A common-mode signal is an average voltage of the two signal wires that the differential receiver rejects. The common-mode signal comes from the CAN driver, ground noise, and coupled bus noise. Since the bias voltage of the recessive state of the device is dependent on V_{CC} , any noise present or variation of V_{CC} has an effect on this bias voltage seen by the bus. The TCAN33x family has the recessive bias voltage set higher than $0.5 \times V_{CC}$ to match common mode in recessive mode to dominant mode. This results in superior EMC performance.

7.4 Power Supply Recommendations

For reliable operation at all data rates and supply voltages, each supply should be decoupled with a 100nF ceramic capacitor located as close to the V_{CC} supply pins as possible. The TPS76333 is a linear voltage regulator suitable for the 3.3V supply.

7.5 Layout

7.5.1 Layout Guidelines

TCAN33x family of devices incorporates integrated IEC 61000-4-2 ESD protection. Should the system requires additional protection against ESD, EFT or surge, additional external protection and filtering circuitry may be needed.

In order for the PCB design to be successful, start with design of the protection and filtering circuitry. Because ESD and EFT transients have a wide frequency bandwidth from approximately 3MHz to 3GHz, high frequency layout techniques must be applied during PCB design.

Design the bus protection components in the direction of the signal path. Do not force the transient current to divert from the signal path to reach the protection device. Below is a list of layout recommendations when designing a CAN transceiver into an application.

- Transient Protection on CANH and CANL: Transient Voltage Suppression (TVS) and capacitors (D1, C5 and C7 shown in [图 7-7](#)) can be used for additional system level protection. These devices must be placed as close to the connector as possible. This prevents the transient energy and noise from penetrating into other nets on the board.
- Bus Termination on CANH and CANL: [图 7-7](#) shows split termination where the termination is split into two resistors, R5 and R6, with the center or split tap of the termination connected to ground through capacitor C6. Split termination provides common mode filtering for the bus. When termination is placed on the board instead of directly on the bus, care must be taken to ensure the terminating node is not removed from the bus, as this causes signal integrity issues if the bus is not properly terminated on both ends.
- Decoupling Capacitors on V_{CC} : Bypass and bulk capacitors must be placed as close as possible to the supply pins of transceiver (examples are C2 and C3).
- Ground and power connections: Use at least two vias for V_{CC} and ground connections of bypass capacitors and protection devices to minimize trace and via inductance.
- Digital inputs and outputs: To limit current of digital lines, serial resistors may be used. Examples are R1, R2, R3 and R4.
- Filtering noise on digital inputs and outputs: To filter noise on the digital I/O lines, a capacitor may be used close to the input side of the I/O as shown by C1, C8 and C4.
- Fault Output Pin (TCAN337 only): Because the FAULT output pin is an open drain output, an external pullup resistor is required to pull the pin voltage high for normal operation (R7).
- TXD input pin: If an open-drain host processor is used to drive the TXD pin of the device, an external pullup resistor between $1k\ \Omega$ and $10k\ \Omega$ must be used to help drive the recessive input state of the device (weak internal pullup resistor).

7.5.2 Layout Example

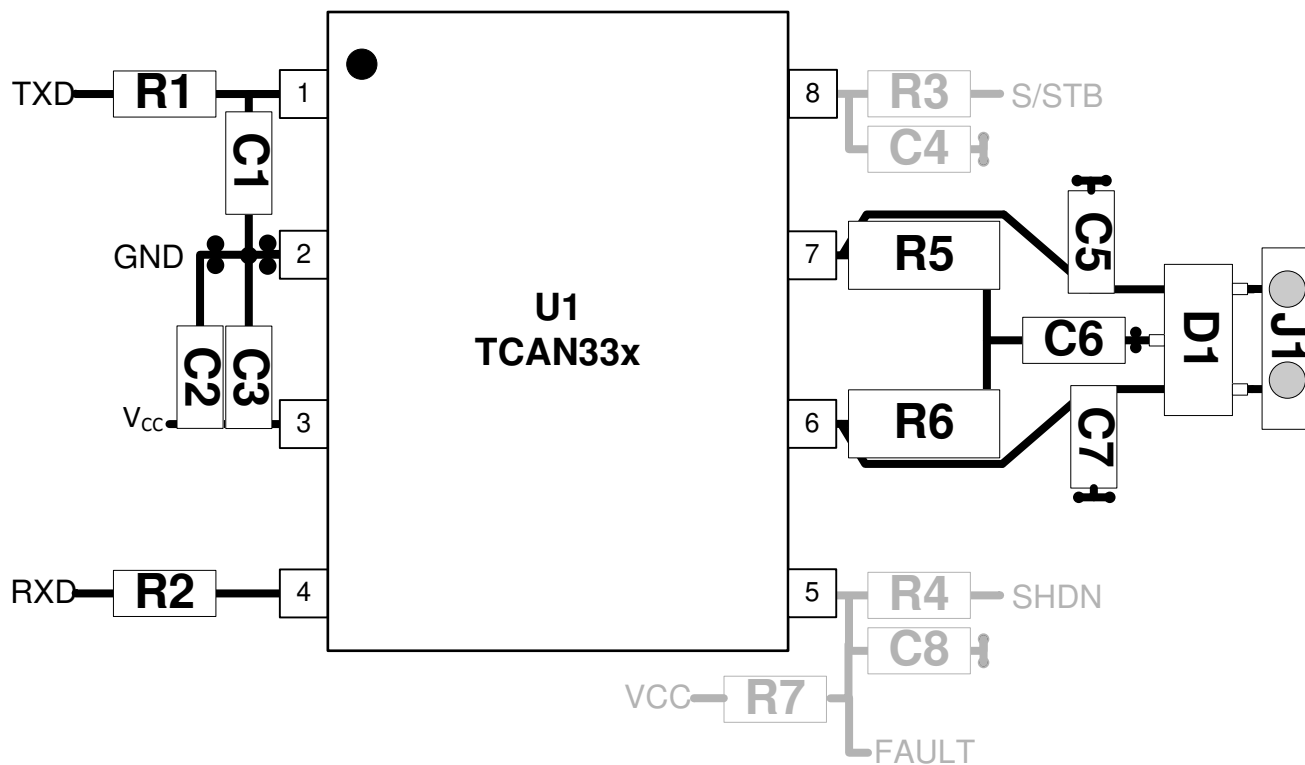


图 7-7. Layout Example

Device and Documentation Support

1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

2 支持资源

TI E2E™ 中文支持论坛 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

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4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

5 术语表

TI 术语表 本术语表列出并解释了术语、首字母缩略词和定义。

8 Revision History

Changes from Revision E (December 2019) to Revision F (May 2025)	Page
--	------

- | | |
|----------------------------------|---|
| • 将“器件信息”表更改为 封装信息 表..... | 1 |
|----------------------------------|---|

Changes from Revision D (April 2016) to Revision E (December 2019)	Page
--	------

- | | |
|---|---|
| • Changed the Pin Configuration image appearance..... | 4 |
| • Changed the titles of 图 6-4 and 图 6-5 | 3 |

Changes from Revision C (April 2016) to Revision D (April 2016)	Page
---	------

- | | |
|---|---|
| • 将 节 2 列表中的 ARNIC825 更改为 ARINC825..... | 1 |
|---|---|

Changes from Revision B (April 2016) to Revision C (April 2016)	Page
---	------

- | | |
|--|---|
| • Removed the Preview Note from TCAN337 and TCAN337G in the <i>Device Options</i> table..... | 3 |
|--|---|

Changes from Revision A (January 2016) to Revision B (April 2016)	Page
---	------

- | | |
|---|---|
| • Removed the Preview Note from all device except for TCAN337 and TCAN337G in the <i>Device Comparison</i> table..... | 3 |
|---|---|

- Changed FAULT Pin I_{CL} MIN value From: 5mA To: 4mA in the [节 5.5](#)6

Changes from Revision * (December 2015) to Revision A (January 2016)	Page
• 将 节 1 从“总环路延迟 < 150ns”至：“总环路延迟 < 135ns”	1
• Changed $V_{IT(SLEEP)}$ To: $V_{IT(STB)}$ and added Test conditions in the 节 5.5	6
• Added $-12V < V_{CM} < 12V$ to t_{WK_FILTER} in the Test Conditions of 节 5.6	9

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TCAN330D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330DCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330DCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330DCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330DCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330GD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330GD.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330GDCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330GDCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330GDCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330GDCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	330
TCAN330GDG4	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330GDG4.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330GDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN330GDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC330
TCAN332D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332DCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332DCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332DCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332DCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332DCNTG4	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332DCNTG4.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332DRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
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TCAN332GD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332GD.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332GDCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332GDCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332GDCNRG4	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332GDCNRG4.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332GDCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332GDCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	332
TCAN332GDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332GDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332GDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN332GDRG4.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC332
TCAN334D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334DCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334DCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334DCNRG4	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334DCNRG4.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334DCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334DCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334DRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334DRG4.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334GD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334GD.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334GDCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334GDCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334GDCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334GDCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334

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TCAN334GDCNTG4.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	334
TCAN334GDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN334GDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC334
TCAN337D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337DCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337DCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337DCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337DCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337GD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337GD.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337GDCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337GDCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337GDCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337GDCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337GDCNTG4	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337GDCNTG4.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	337
TCAN337GDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337GDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337GDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337
TCAN337GDRG4.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TC337

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

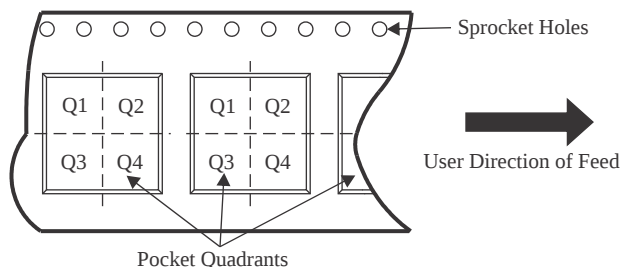
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TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCAN330DCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN330DCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN330DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN330GDCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN330GDCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN330GDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN332DCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN332DCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN332DCNTG4	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN332DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN332DRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN332GDCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN332GDCNRG4	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN332GDCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN332GDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN332GDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCAN334DCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN334DCNRG4	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN334DCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN334DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN334DRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN334GDCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN334GDCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN334GDCNTG4	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN334GDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN337DCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN337DCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN337DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN337GDCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN337GDCNT	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN337GDCNTG4	SOT-23	DCN	8	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TCAN337GDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TCAN337GDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

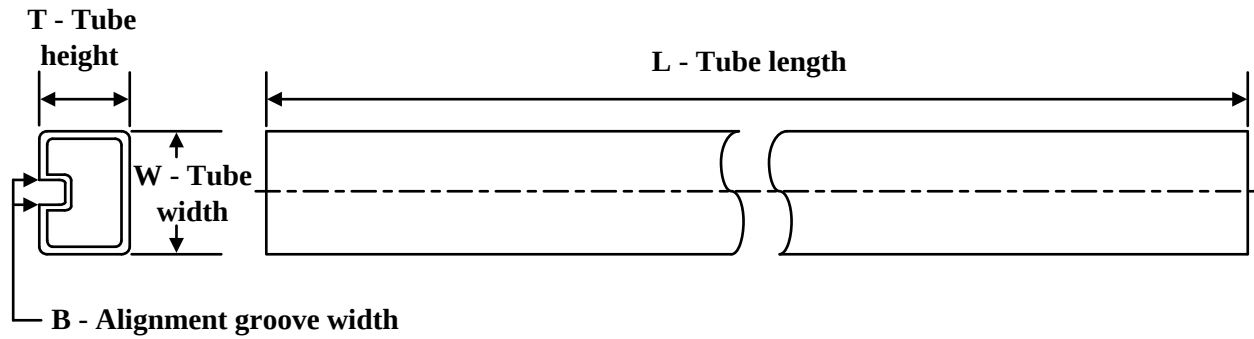
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCAN330DCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN330DCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN330DR	SOIC	D	8	2500	353.0	353.0	32.0
TCAN330GDCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN330GDCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN330GDR	SOIC	D	8	2500	353.0	353.0	32.0
TCAN332DCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN332DCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN332DCNTG4	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN332DR	SOIC	D	8	2500	353.0	353.0	32.0
TCAN332DRG4	SOIC	D	8	2500	353.0	353.0	32.0
TCAN332GDCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN332GDCNRG4	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN332GDCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN332GDR	SOIC	D	8	2500	353.0	353.0	32.0
TCAN332GDRG4	SOIC	D	8	2500	353.0	353.0	32.0
TCAN334DCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN334DCNRG4	SOT-23	DCN	8	3000	202.0	201.0	28.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCAN334DCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN334DR	SOIC	D	8	2500	353.0	353.0	32.0
TCAN334DRG4	SOIC	D	8	2500	353.0	353.0	32.0
TCAN334GDCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN334GDCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN334GDCNTG4	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN334GDR	SOIC	D	8	2500	353.0	353.0	32.0
TCAN337DCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN337DCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN337DR	SOIC	D	8	2500	340.5	336.1	25.0
TCAN337GDCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TCAN337GDCNT	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN337GDCNTG4	SOT-23	DCN	8	250	202.0	201.0	28.0
TCAN337GDR	SOIC	D	8	2500	353.0	353.0	32.0
TCAN337GDRG4	SOIC	D	8	2500	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TCAN330D	D	SOIC	8	75	507	8	3940	4.32
TCAN330D.B	D	SOIC	8	75	507	8	3940	4.32
TCAN330GD	D	SOIC	8	75	507	8	3940	4.32
TCAN330GD.B	D	SOIC	8	75	507	8	3940	4.32
TCAN330GDG4	D	SOIC	8	75	507	8	3940	4.32
TCAN330GDG4.B	D	SOIC	8	75	507	8	3940	4.32
TCAN332D	D	SOIC	8	75	507	8	3940	4.32
TCAN332D.B	D	SOIC	8	75	507	8	3940	4.32
TCAN332GD	D	SOIC	8	75	507	8	3940	4.32
TCAN332GD.B	D	SOIC	8	75	507	8	3940	4.32
TCAN334D	D	SOIC	8	75	507	8	3940	4.32
TCAN334D.B	D	SOIC	8	75	507	8	3940	4.32
TCAN334GD	D	SOIC	8	75	507	8	3940	4.32
TCAN334GD.B	D	SOIC	8	75	507	8	3940	4.32
TCAN337D	D	SOIC	8	75	507	8	3940	4.32
TCAN337D.B	D	SOIC	8	75	507	8	3940	4.32
TCAN337GD	D	SOIC	8	75	507	8	3940	4.32
TCAN337GD.B	D	SOIC	8	75	507	8	3940	4.32

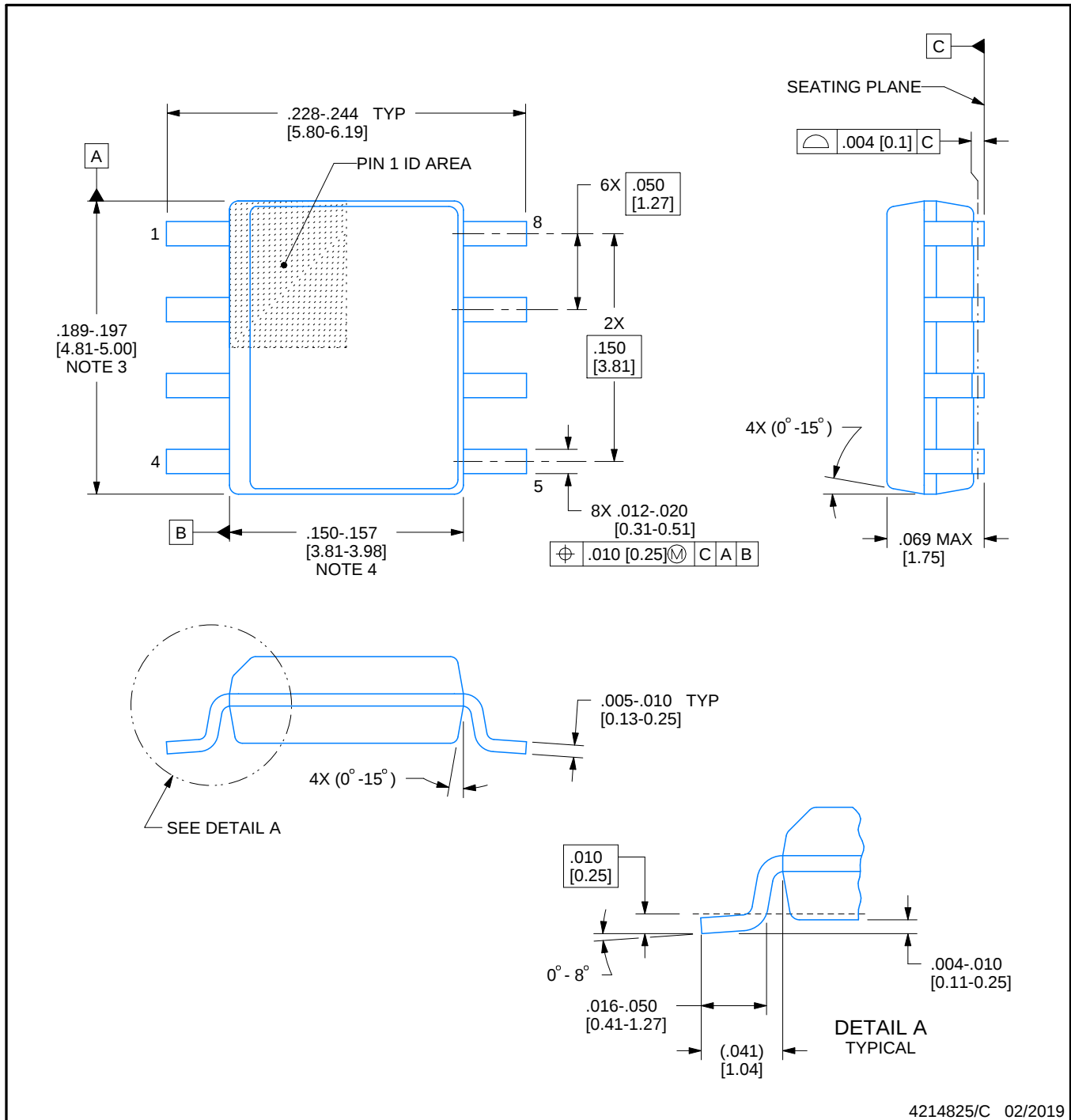


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

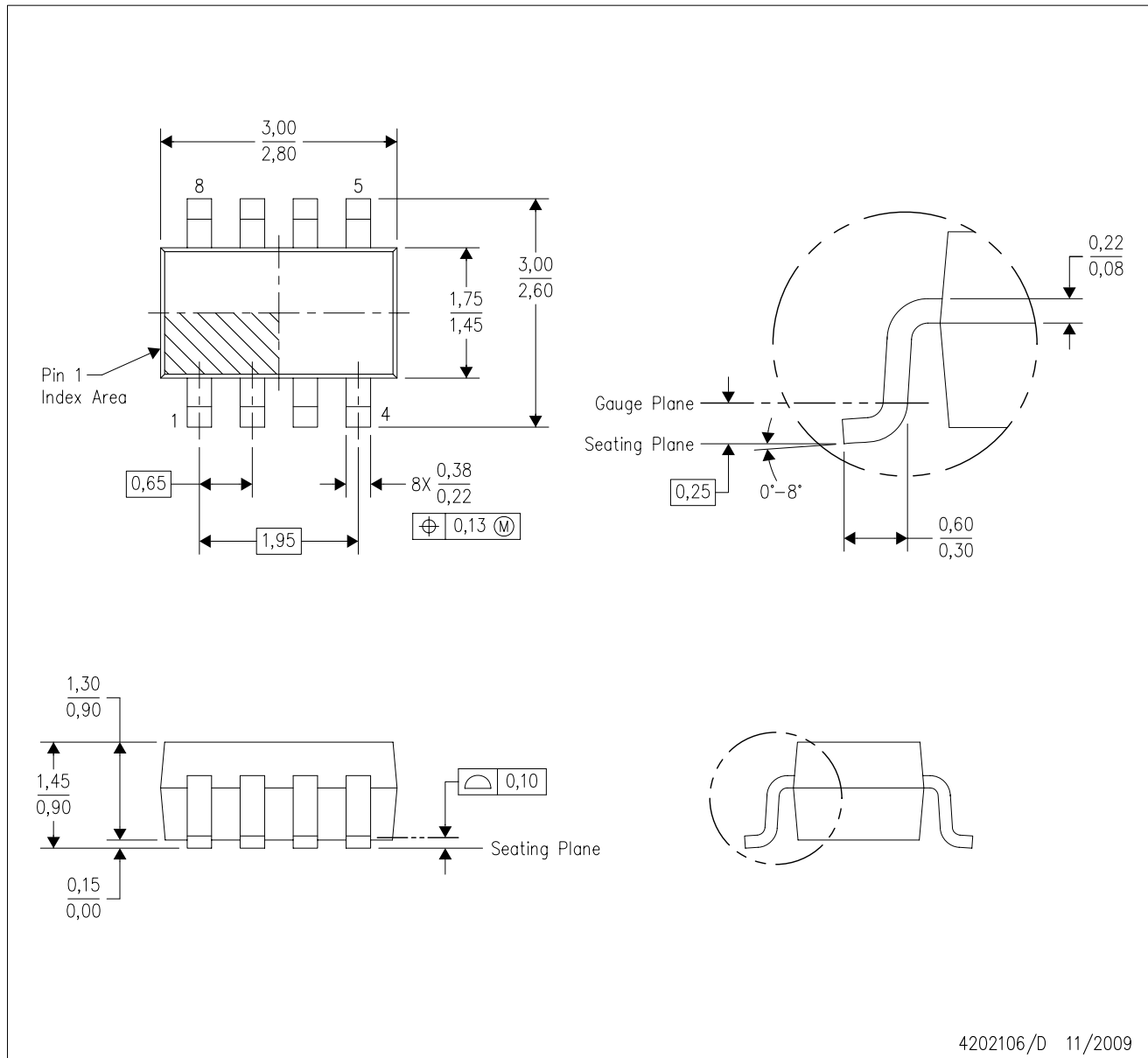
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DCN (R-PDSO-G8)

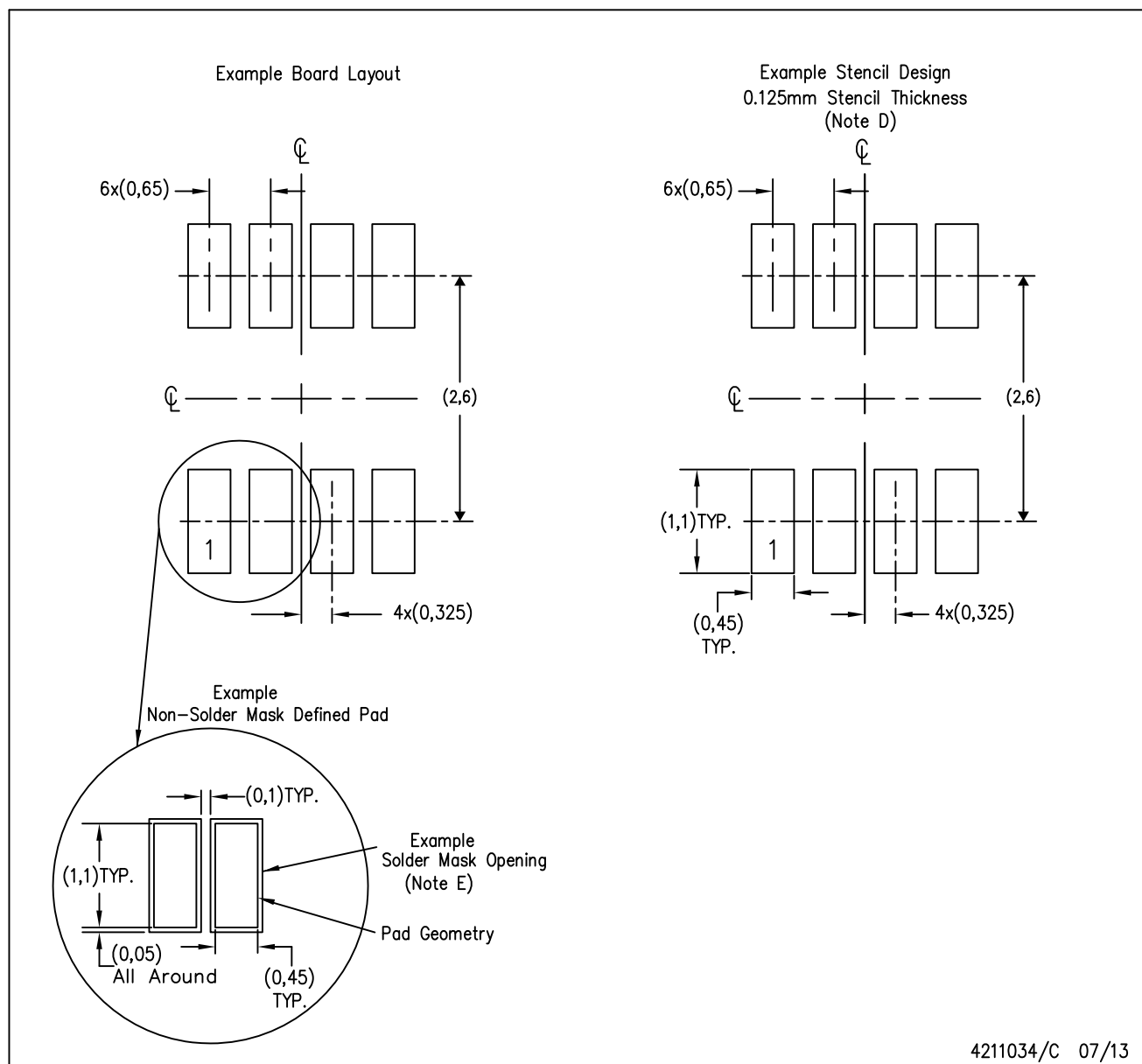
PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Package outline exclusive of metal burr & dambar protrusion/intrusion.
 - D. Package outline inclusive of solder plating.
 - E. A visual index feature must be located within the Pin 1 index area.
 - F. Falls within JEDEC MO-178 Variation BA.
 - G. Body dimensions do not include flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

DCN (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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